

# MWCT101xSF

## MWCT101xS Data Sheet

### Key Features

- Operating characteristics
  - Voltage range: 2.7 V to 5.5 V
  - Ambient temperature range: -40 °C to 105 °C for HSRUN, -40 °C to 125 °C for RUN
- ARM™ Cortex-M4F/M0+ core, 32-bit CPU
  - Supports up to 112 MHz frequency with 1.25 Dhrystone MIPS per MHz
  - ARM Core based on the ARMv7 Architecture and Thumb®-2 ISA
  - Integrated Digital Signal Processor (DSP)
  - Configurable Nested Vectored Interrupt Controller (NVIC)
  - Single Precision Floating Point Unit (FPU)
- Clock interfaces
  - 4 - 40 MHz fast external oscillator (SOSC)
  - 48 MHz Fast Internal RC oscillator (FIRC)
  - 8 MHz Slow Internal RC oscillator (SIRC)
  - 128 kHz Low Power Oscillator (LPO)
  - Up to 112 MHz System Phased Lock Loop (SPLL)
  - Up to 50 MHz DC external square wave input clock
  - Real Time Counter (RTC)
- Power management
  - Low-power ARM Cortex-M4F/M0+ core with excellent energy efficiency
  - Power Management Controller (PMC) with multiple power modes: HSRUN, Run, Stop, VLPR, and VLPS
  - Supports peripheral specific clock gating. Only specific peripherals remain working in low power modes.
- Memory and memory interfaces
  - Up to 2 MB program flash memory with ECC
  - 64 KB FlexNVM for data flash memory with ECC and EEPROM emulation
  - Up to 256 KB SRAM with ECC
  - Up to 4 KB of FlexRAM for use as SRAM or EEPROM emulation
  - Up to 4 KB Code cache to minimize performance impact of memory access latencies
  - QuadSPI with HyperBus™ support
- Mixed-signal analog
  - Up to two 12-bit Analog-to-Digital Converter (ADC) with up to 32 channel analog inputs per module
  - One Analog Comparator (CMP) with internal 8-bit Digital to Analog Converter (DAC)
- Debug functionality
  - Serial Wire JTAG Debug Port (SWJ-DP) combines
  - Debug Watchpoint and Trace (DWT)
  - Instrumentation Trace Macrocell (ITM)
  - Test Port Interface Unit (TPIU)
  - Flash Patch and Breakpoint (FPB) Unit
- Human-machine interface (HMI)
  - Up to 156 GPIO pins with interrupt functionality
  - Non-Maskable Interrupt (NMI)
- Communications interfaces
  - Up to three Low Power Universal Asynchronous Receiver/Transmitter (LPUART) modules with DMA support and low power availability
  - Up to three Low Power Serial Peripheral Interface (LPSPI) modules with DMA support and low power availability
  - Up to two Low Power Inter-Integrated Circuit (I2C) modules with DMA support and low power availability
  - Up to three FlexCAN modules (with optional CAN-FD support)
  - FlexIO module for flexible and high performance serial interfaces
- Reliability, safety and security
  - HW Security Engine (CSEc)
  - Internal watchdog (WDOG)
  - External Watchdog monitor (EWM) module
  - Error-Correcting Code (ECC) on flash and SRAM memories
  - Cyclic Redundancy Check (CRC) module
  - 128-bit Unique Identification (ID) number
  - System Memory Protection Unit (System MPU)

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- Timing and control
  - Up eight independent 16-bit FlexTimers (FTM) module, offering up to 64 standard channels (IC/OC/PWM)
  - One 16-bit Low Power Timer (LPTMR) with flexible wake up control
  - Two Programmable Delay Blocks (PDB) with flexible trigger system
  - One 32-bit Low Power Interrupt Timer (LPIT) with 4 channels
  - 32-bit Real Time Counter (RTC)
- I/O and package
  - 64-pin LQFP, 100-pin LQFP
- 16 channel DMA with up to 63 request sources using DMAMUX

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# 1 Block diagram

The figure below shows a superset high level architecture block diagram of the device. Other devices within the family have a subset of the features. See [Feature comparison](#) for chip specific values.

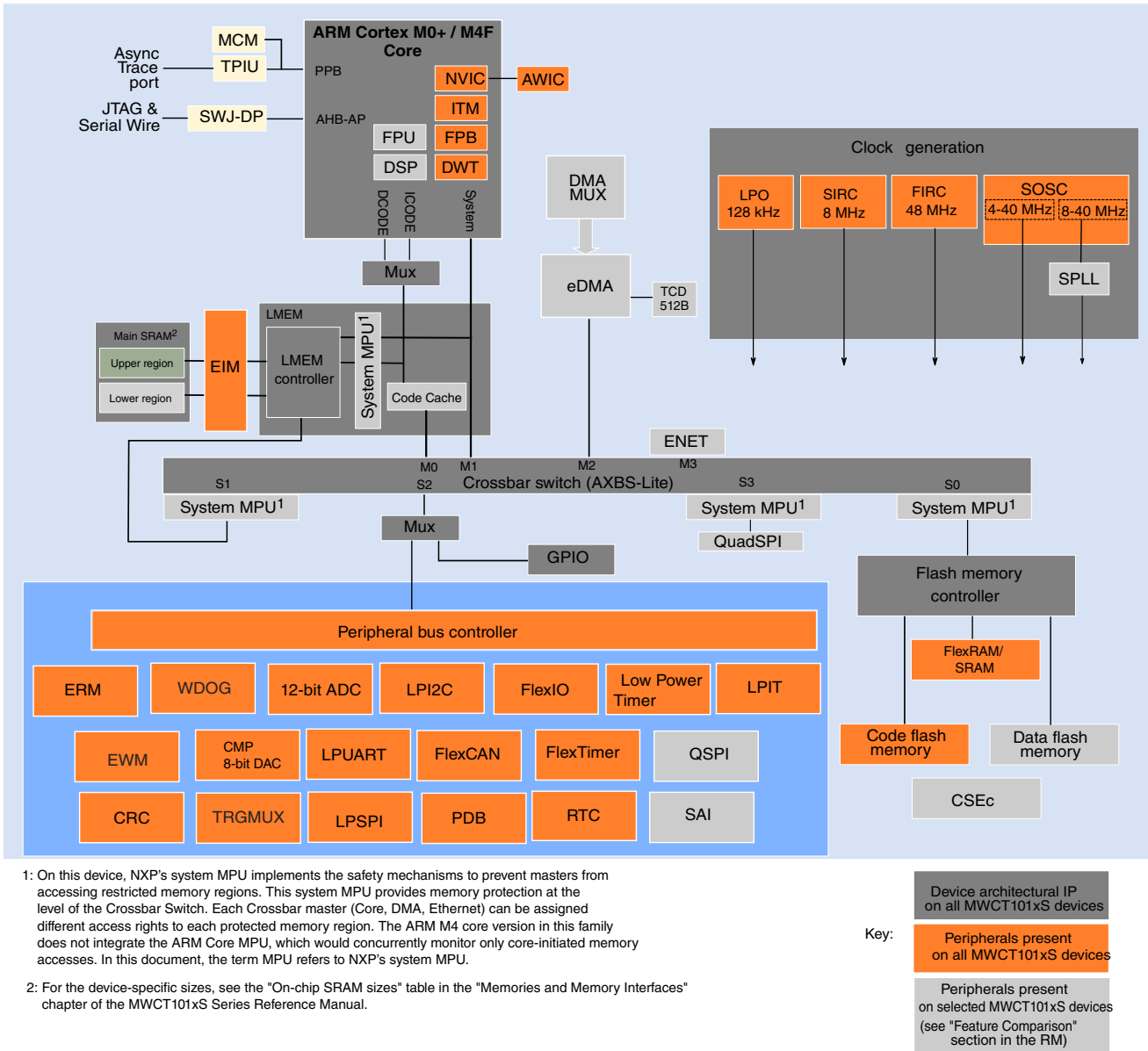


Figure 1. High-level architecture diagram for the MWCT101xS family

## 2 Feature comparison

The following figure summarizes the memory and package options for the MWCT101xS series and demonstrates where this device fits within the overall series. All devices which share a common package are pin-to-pin compatible.

|               |                                                                                  | MWCT101xS                                                                 |                     |                                                     |
|---------------|----------------------------------------------------------------------------------|---------------------------------------------------------------------------|---------------------|-----------------------------------------------------|
| Parameter     |                                                                                  | MWCT1014S                                                                 | MWCT1015S           | MWCT1016S                                           |
| System        | Core                                                                             | ARM® Cortex™-M4F                                                          |                     |                                                     |
|               | Frequency                                                                        | up to 112 MHz                                                             |                     |                                                     |
|               | IEEE-754 FPU                                                                     | ●                                                                         |                     |                                                     |
|               | HW security module (CSEc)                                                        | ●                                                                         |                     |                                                     |
|               | CRC module                                                                       | 1x                                                                        |                     |                                                     |
|               | ISO 26262                                                                        | capable up to ASIL-B                                                      |                     |                                                     |
|               | Peripheral speed                                                                 | up to 112 MHz                                                             |                     |                                                     |
|               | Crossbar                                                                         | ●                                                                         |                     |                                                     |
|               | DMA                                                                              | ●                                                                         |                     |                                                     |
|               | EWM                                                                              | ●                                                                         |                     |                                                     |
|               | Memory protection unit                                                           | ●                                                                         |                     |                                                     |
|               | FIRC CMU                                                                         | ○                                                                         |                     |                                                     |
|               | Watchdog                                                                         | 1x                                                                        |                     |                                                     |
|               | Low power modes                                                                  | ●                                                                         |                     |                                                     |
|               | HSRUN mode                                                                       | ●                                                                         |                     |                                                     |
|               | Number of I/Os                                                                   | up to 89                                                                  | up to 128           | up to 156                                           |
|               | Single supply voltage                                                            | 2.7 - 5.5 V                                                               |                     |                                                     |
|               | Operating temperature (T <sub>a</sub> ) Temperature ambient                      | -40 to +85°C / +105°C / +125°C                                            |                     |                                                     |
| Memory        | Flash                                                                            | 512 KB                                                                    | 1 MB                | 2 MB                                                |
|               | Error correction code (ECC)                                                      | ●                                                                         |                     |                                                     |
|               | System RAM (including FlexRAM and MTB)                                           | 64 KB                                                                     | 128 KB              | 256 KB                                              |
|               | FlexRAM (also available as system RAM)                                           | 4 KB                                                                      |                     |                                                     |
|               | Cache                                                                            | 4 KB                                                                      |                     |                                                     |
|               | EEPROM emulated by FlexRAM                                                       | 4 KB (up to 64 KB D-Flash)                                                |                     | 4 KB (up to 512 KB D-Flash as a part of 2 MB Flash) |
|               | External memory interface                                                        | ○                                                                         |                     | QuadSPI incl. HyperBus™                             |
| Timer         | Low power interrupt timer                                                        | 1x                                                                        |                     |                                                     |
|               | FlexTimer (16-bit counter) 8 channels                                            | 4x (32)                                                                   | 6x (48)             | 8x (64)                                             |
|               | Low power timer (LPTMR)                                                          | 1x                                                                        |                     |                                                     |
|               | Real time counter (RTC)                                                          | 1x                                                                        |                     |                                                     |
|               | Programmable delay block (PDB)                                                   | 2x                                                                        |                     |                                                     |
| Analog        | Trigger mux (TRGMUX)                                                             | 1x (64)                                                                   | 1x (73)             | 1x (81)                                             |
|               | 12-bit SAR ADC (1 MSPS each)                                                     | 2x (16)                                                                   | 2x (24)             | 2x (32)                                             |
|               | Comparator with 8-bit DAC                                                        | 1x                                                                        |                     |                                                     |
| Communication | 100 Mbit IEEE-1588 ethernet MAC                                                  | ○                                                                         |                     | 1x                                                  |
|               | Serial audio interface (AC97, TDM, I2S)                                          | ○                                                                         |                     | 2x                                                  |
|               | Low power UART/LIN (Supports LIN protocol versions 1.3, 2.0, 2.1, and SAE J2602) | 2x                                                                        | 3x                  |                                                     |
|               | Low power SPI                                                                    | 2x                                                                        | 3x                  |                                                     |
|               | Low power I2C                                                                    | 1x                                                                        |                     | 2x                                                  |
|               | FlexCAN (CAN-FD ISO/CD 11898-1)                                                  | 3x (1x with FD)                                                           | 3x (2x with FD)     | 3x (3x with FD)                                     |
|               | FlexIO (8 pins configurable as UART, SPI, I2C, I2S)                              | 1x                                                                        |                     |                                                     |
| IDEs          | Debug & trace                                                                    | SWD, JTAG (ITM, SWV, SWO)                                                 |                     | SWD, JTAG (ITM, SWV, SWO), ETM                      |
|               | Ecosystem (IDE, compiler, debugger)                                              | NXP S32 Design Studio (GCC) + SDK, IAR, GHS, COSMIC, Lauterbach, iSystems |                     |                                                     |
| Other         | Packages                                                                         | LQFP-64<br>LQFP-100                                                       | LQFP-64<br>LQFP-100 | LQFP-64<br>LQFP-100                                 |

LEGEND:  
 ○ Not implemented.  
 ● Available on the device.  
 1 Only for BSR

Figure 2. MWCT101xS product series comparison

## 3 Ordering parts

### 3.1 Determining valid orderable parts

To determine the orderable part numbers for this device, go to [www.nxp.com](http://www.nxp.com) and perform a part number search.

#### **NOTE**

Not all part number combinations exist

## 3.2 Ordering information

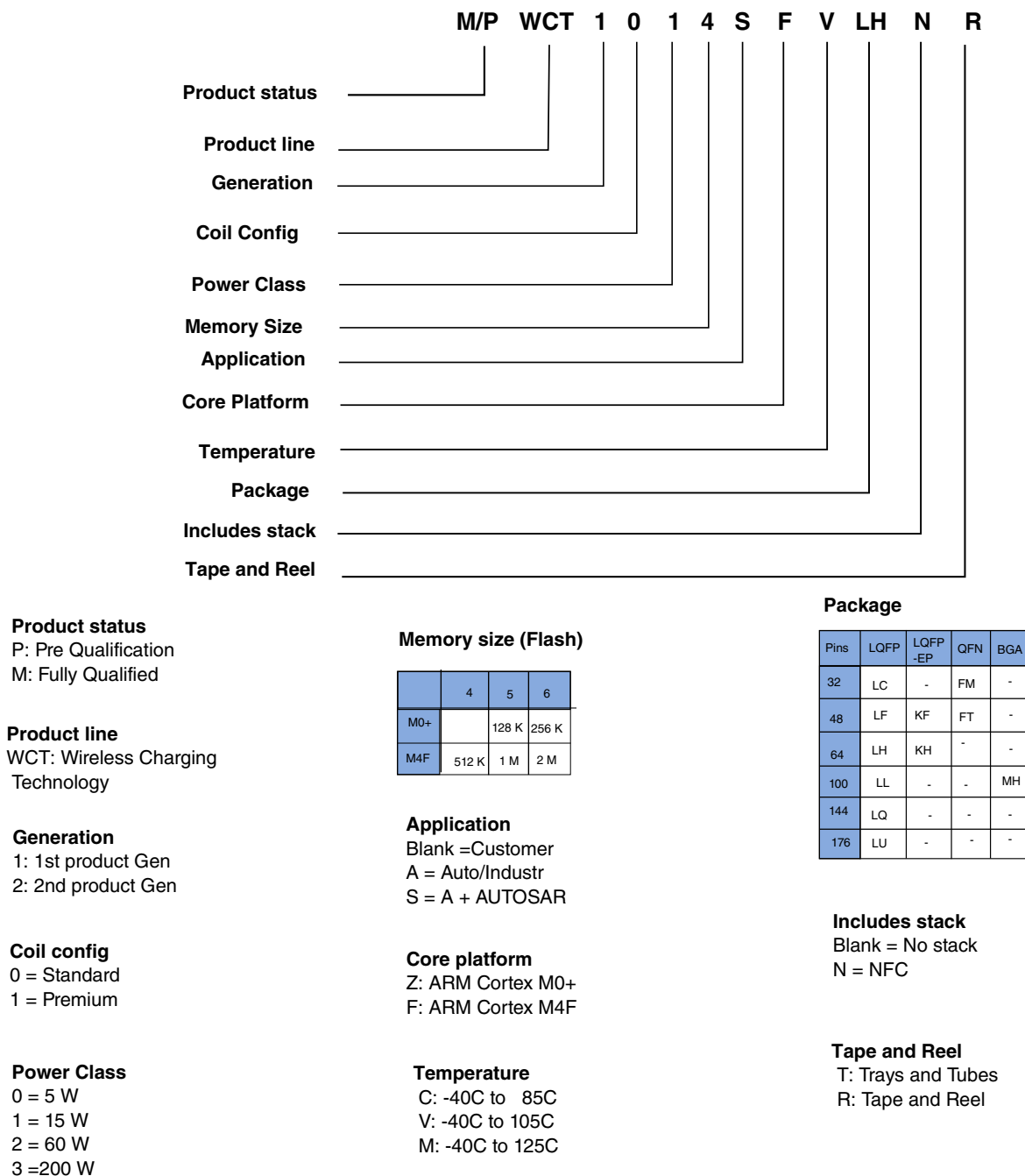


Figure 3. Ordering information

## 4 General

### 4.1 Absolute maximum ratings

#### NOTE

Functional operating conditions appear in the DC electrical characteristics. Absolute maximum ratings are stress ratings only, and functional operation at the maximum values is not guaranteed. See footnotes in the following table for specific conditions.

Stress beyond the listed maximum values may affect device reliability or cause permanent damage to the device.

**Table 1. Absolute maximum ratings<sup>1</sup>**

| Symbol                        | Parameter                                                                              | Conditions <sup>2</sup> | Min       | Max              | Unit |
|-------------------------------|----------------------------------------------------------------------------------------|-------------------------|-----------|------------------|------|
| $V_{DD}$ <sup>3</sup>         | 2.7 V - 5.5 V input supply voltage                                                     | —                       | -0.3      | 5.8 <sup>4</sup> | V    |
| $V_{REFH}$                    | 3.3 V / 5.0 V ADC high reference voltage                                               | —                       | -0.3      | 5.8 <sup>4</sup> | V    |
| $I_{INJPAD\_DC}$ <sup>5</sup> | Continuous DC input current (positive / negative) that can be injected into an I/O pin | —                       | -3        | +3               | mA   |
| $V_{IN\_DC}$                  | Continuous DC Voltage on any I/O pin with respect to $V_{SS}$                          | —                       | -0.8      | 5.5 <sup>6</sup> | V    |
| $I_{INJSUM}$                  | Sum of absolute value of injected currents on all the pins (Continuous DC limit)       | —                       | —         | 30               | mA   |
| $T_{ramp}$ <sup>7</sup>       | Supply ramp rate                                                                       | —                       | 0.5 V/min | 500 V/ms         | —    |
| $T_A$ <sup>8</sup>            | Ambient temperature                                                                    | —                       | -40       | 125              | °C   |
| $T_{STG}$                     | Storage temperature                                                                    | —                       | -55       | 165              | °C   |
| $V_{IN\_TRANSIENT}$           | Transient overshoot voltage allowed on I/O pin beyond $V_{IN\_DC}$ limit               | —                       | —         | 6.8 <sup>9</sup> | V    |

1. All the limits defined in this table are required to be honored even in presence of current injection condition on I/Os.
2. All voltages are referred to  $V_{SS}$  unless otherwise specified.
3. As  $V_{DD}$  varies between the minimum value and the absolute maximum value the analog characteristics of the I/O and the ADC will both change. See section [I/O parameters](#) and [ADC electrical specifications](#) respectively for details.
4. 60 s lifetime – No restrictions i.e. The part can switch.  
10 hours lifetime – Device in reset i.e. The part cannot switch.
5. When input pad voltage levels are close to  $V_{DD}$  or  $V_{SS}$ , practically no current injection is possible.
6. While respecting the maximum current injection limit
7. Limit applies to both maximum absolute maximum ramp rate and typical operating conditions.
8.  $T_J$  (Junction temperature)=135 °C. Assumes  $T_A$ =125 °C for RUN mode  
 $T_J$  (Junction temperature)=125 °C. Assumes  $T_A$ =105 °C for HSRUN mode
  - Assumes maximum  $\theta_{JA}$  for 2s2p board. See [Thermal characteristics](#)
9. 60 seconds lifetime; device in reset (no outputs enabled/toggling)

## 4.2 Voltage and current operating requirements

### NOTE

Full functionality/specifications cannot be guaranteed when voltage drops below 2.7 V.

**Table 2. Voltage and current operating requirements 1, 2**

| Symbol                | Description                                                                                                   | Min.             | Max.            | Unit | Notes |
|-----------------------|---------------------------------------------------------------------------------------------------------------|------------------|-----------------|------|-------|
| $V_{DD}$ <sup>3</sup> | Supply voltage                                                                                                | 2.7 <sup>4</sup> | 5.5             | V    | 5     |
| $V_{DD\_OFF}$         | Voltage allowed to be developed on $V_{DD}$ pin when it is not powered from any external power supply source. | TBD              | 0.1             | V    |       |
| $V_{DDA}$             | Analog supply voltage                                                                                         | 2.7              | 5.5             | V    | 5     |
| $V_{DD} - V_{DDA}$    | $V_{DD}$ -to- $V_{DDA}$ differential voltage                                                                  | -0.1             | 0.1             | V    |       |
| $V_{REFH}$            | ADC reference voltage high                                                                                    | 2.7              | $V_{DDA} + 0.1$ | V    | 6     |
| $V_{REFL}$            | ADC reference voltage low                                                                                     | -0.1             | 0.1             | V    |       |
| $V_{ODPU}$            | Open drain pullup voltage level                                                                               | $V_{DD}$         | $V_{DD}$        | V    | 7     |

1. All the limits defined in this table are required to be honored even in presence of current injection condition on I/Os.
2. Typical conditions assumes  $V_{DD} = V_{DDA} = V_{REFH} = 5$  V, temperature = 25 °C and typical silicon process unless otherwise stated.
3. As  $V_{DD}$  varies between the minimum value and the absolute maximum value the analog characteristics of the I/O and the ADC will both change. See section [I/O parameters](#) and [ADC electrical specifications](#) respectively for details.
4. MWCT1016S will operate from 2.7 V when executing from internal FIRC. When the PLL is engaged MWCT1016S is guaranteed to operate from 2.97 V. All other MWCT101xS family devices operate from 2.7 V in all modes.
5.  $V_{DD}$  and  $V_{DDA}$  must be shorted to a common source on PCB. Appropriate decap to be used to filter noise on  $V_{DDA}$ . See application note [AN5032](#) for reference supply design for SAR ADC.
6.  $V_{REFH}$  should always be equal to or less than  $V_{DDA} + 0.1$  V and  $V_{DD} + 0.1$  V
7. Open drain outputs must be pulled to  $V_{DD}$ .

## 4.3 Thermal operating characteristics

**Table 3. Thermal operating characteristics for 64 LQFP, 100 LQFP, and 100 MAP-BGA packages.**

| Symbol             | Parameter                       | Value |      |                  | Unit |
|--------------------|---------------------------------|-------|------|------------------|------|
|                    |                                 | Min.  | Typ. | Max.             |      |
| $T_A$ C-Grade Part | Ambient temperature under bias  | -40   | —    | 85 <sup>1</sup>  | °C   |
| $T_J$ C-Grade Part | Junction temperature under bias | -40   | —    | 105 <sup>1</sup> | °C   |
| $T_A$ V-Grade Part | Ambient temperature under bias  | -40   | —    | 105 <sup>1</sup> | °C   |
| $T_J$ V-Grade Part | Junction temperature under bias | -40   | —    | 125 <sup>1</sup> | °C   |
| $T_A$ M-Grade Part | Ambient temperature under bias  | -40   | —    | 125 <sup>2</sup> | °C   |
| $T_J$ M-Grade Part | Junction temperature under bias | -40   | —    | 135 <sup>2</sup> | °C   |

1. Values mentioned are measured at  $\leq 112$  MHz in HSRUN mode.

2. Values mentioned are measured at  $\leq 80$  MHz in RUN mode.

## 4.4 Power and ground pins

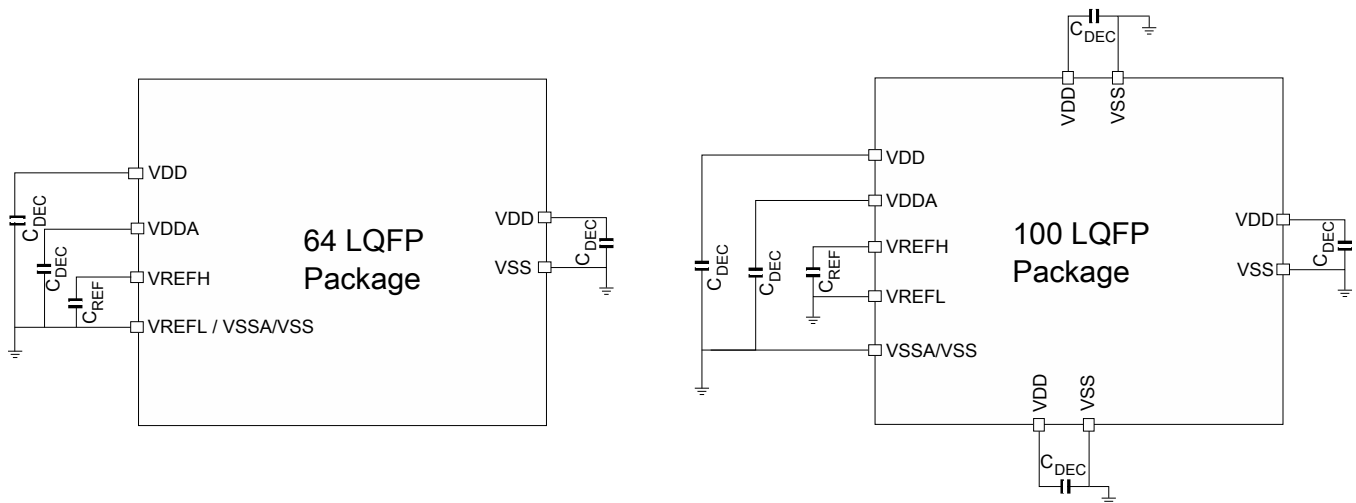
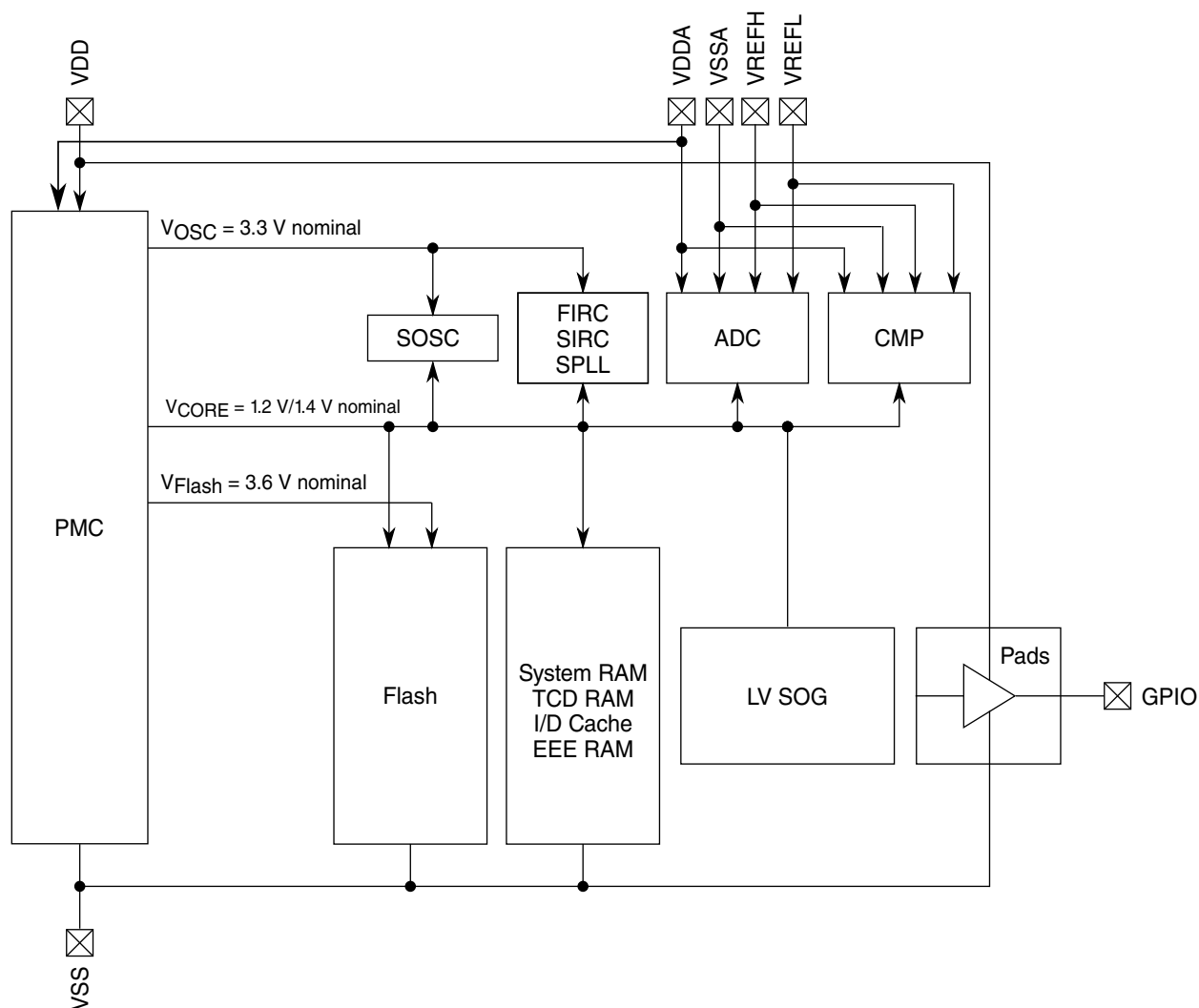


Figure 4. Pinout decoupling

Table 4. Supplies decoupling capacitors 1, 2

| Symbol                       | Description                               | Min. <sup>3</sup> | Typ. | Max. | Unit |
|------------------------------|-------------------------------------------|-------------------|------|------|------|
| $C_{REF}$ <sup>4, 5</sup>    | ADC reference high decoupling capacitance | 70                | 100  | —    | nF   |
| $C_{DEC}$ <sup>5, 6, 7</sup> | Recommended decoupling capacitance        | 70                | 100  | —    | nF   |

- $V_{DD}$  and  $V_{DDA}$  must be shorted to a common source on PCB. Appropriate decoupling capacitors to be used to filter noise on the supplies. See application note AN5032 for reference supply design for SAR ADC. All  $V_{SS}$  pins should be connected to common ground at the PCB level.
- All decoupling capacitors must be low ESR ceramic capacitors (for example X7R type).
- Minimum recommendation is after considering component aging and tolerance.
- For improved performance, it is recommended to use 10  $\mu$ F, 0.1  $\mu$ F and 1 nF capacitors in parallel.
- All decoupling capacitors should be placed as close as possible to the corresponding supply and ground pins.
- Contact your local Field Applications Engineer for details on best analog routing practices.
- The filtering used for decoupling the device supplies must comply with the following best practices rules:
  - The protection/decoupling capacitors must be on the path of the trace connected to that component.
  - No trace exceeding 1 mm from the protection to the trace or to the ground.
  - The protection/decoupling capacitors must be as close as possible to the input pin of the device (maximum 2 mm).
  - The ground of the protection is connected as short as possible to the ground plane under the integrated circuit.



\*Note: VSSA and VSS are shorted at package level

**Figure 5. Power diagram**

## 4.5 LVR, LVD and POR operating requirements

**Table 5.  $V_{DD}$  supply LVR, LVD and POR operating requirements**

| Symbol          | Description                                        | Min. | Typ.  | Max. | Unit | Notes |
|-----------------|----------------------------------------------------|------|-------|------|------|-------|
| $V_{POR}$       | Rising and falling $V_{DD}$ POR detect voltage     | 1.1  | 1.6   | 2.0  | V    |       |
| $V_{LVR}$       | LVR falling threshold (RUN, HSRUN, and STOP modes) | 2.50 | 2.58  | 2.7  | V    |       |
| $V_{LVR\_HYST}$ | LVR hysteresis                                     | TBD  | 45    | TBD  | mV   | 1     |
| $V_{LVR\_LP}$   | LVR falling threshold (VLPS/VLPR modes)            | 1.97 | 2.22  | 2.44 | V    |       |
| $V_{LVD}$       | Falling low-voltage detect threshold               | 2.8  | 2.875 | 3    | V    |       |
| $V_{LVD\_HYST}$ | LVD hysteresis                                     | TBD  | 50    | TBD  | mV   | 1     |

Table continues on the next page...

**Table 5.  $V_{DD}$  supply LVR, LVD and POR operating requirements (continued)**

| Symbol          | Description                           | Min. | Typ.  | Max. | Unit | Notes |
|-----------------|---------------------------------------|------|-------|------|------|-------|
| $V_{LVW}$       | Falling low-voltage warning threshold | 4.19 | 4.305 | 4.5  | V    |       |
| $V_{LVW\_HYST}$ | LVW hysteresis                        | TBD  | 75    | TBD  | mV   | 1     |
| $V_{BG}$        | Bandgap voltage reference             | 0.97 | 1.00  | 1.03 | V    |       |

1. Rising threshold is the sum of falling threshold and hysteresis voltage.

## 4.6 Power mode transition operating behaviors

All specifications in the following table assume this clock configuration:

- RUN Mode:
  - Clock source: FIRC
  - SYS\_CLK/CORE\_CLK = 48 MHz
  - BUS\_CLK = 48 MHz
  - FLASH\_CLK = 24 MHz
- HSRUN Mode:
  - Clock source: SPLL
  - SYS\_CLK/CORE\_CLK = 112 MHz
  - BUS\_CLK = 56 MHz
  - FLASH\_CLK = 28 MHz
- VLPR Mode:
  - Clock source: SIRC
  - SYS\_CLK/CORE\_CLK = 4 MHz
  - BUS\_CLK = 4 MHz
  - FLASH\_CLK = 1 MHz
- STOP1/STOP2 Mode:
  - Clock source: FIRC
  - SYS\_CLK/CORE\_CLK = 48 MHz
  - BUS\_CLK = 48 MHz
  - FLASH\_CLK = 24 MHz
- VLPS Mode: All clock sources disabled.

**Table 6. Power mode transition operating behaviors**

| Symbol    | Description <sup>1</sup>                                                                                                                                          | Min. | Typ.  | Max.  | Unit    | Avg IDD <sup>2</sup> |
|-----------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|-------|-------|---------|----------------------|
| $t_{POR}$ | After a POR event, amount of time from the point $V_{DD}$ reaches 2.7 V to execution of the first instruction across the operating temperature range of the chip. | —    | 324.2 | —     | $\mu$ s | TBD                  |
|           | VLPS → RUN                                                                                                                                                        | 7.94 | —     | 16.23 | $\mu$ s | TBD                  |

Table continues on the next page...

**Table 6. Power mode transition operating behaviors (continued)**

| Symbol | Description <sup>1</sup>              | Min.  | Typ. | Max.   | Unit | Avg IDD <sup>2</sup> |
|--------|---------------------------------------|-------|------|--------|------|----------------------|
|        | STOP1 → RUN                           | 1.41  | —    | 2.131  | μs   | TBD                  |
|        | STOP2 → RUN                           | 1.41  | —    | 2.131  | μs   | TBD                  |
|        | VLPR → RUN                            | 18.44 | —    | 25.826 | μs   | TBD                  |
|        | RUN → Compute operation               | 0.83  | —    | 1.007  | μs   | TBD                  |
|        | HSRUN → Compute operation             | 0.351 | —    | 0.482  | μs   | TBD                  |
|        | RUN → STOP1                           | 1.42  | —    | 2.134  | μs   | TBD                  |
|        | RUN → STOP2                           | 1.38  | —    | 2.12   | μs   | TBD                  |
|        | RUN → VLPS                            | 1.42  | —    | 2.134  | μs   | TBD                  |
|        | RUN → VLPR                            | 12.16 | —    | 14.16  | μs   | TBD                  |
|        | VLPS → Asynchronous DMA Wakeup        | TBD   | TBD  | TBD    | μs   | TBD                  |
|        | STOP1/STOP2 → Asynchronous DMA Wakeup | TBD   | TBD  | TBD    | μs   | TBD                  |
|        | Pin reset → Code execution            | —     | 214  | TBD    | μs   | —                    |

1. Times include jumping to ISR and switching the GPIO.

2. Average current consumption during mode transition.

### NOTE

HSRUN should only be used when frequencies in excess of 80 MHz are required. When using 80 MHz and below, RUN mode is the recommended operating mode.

## 4.7 Power consumption

The following table shows the power consumption targets for the device in various mode of operations.

Table 7. Power consumption (Typicals unless stated otherwise) <sup>1</sup>

|                            | Ambient Temperature (°C) |     | VLPS (µA) <sup>2, 3</sup>         |                     | VLPR (mA)            |                     | STOP1 (µA) | STOP2 (µA) | RUN@48 MHz           |                     | RUN@64 MHz           |                     | RUN@80 MHz (mA)      |                     | HSRUN@112 MHz (mA) <sup>4</sup> |                     | Idd/MHz <sup>5</sup> |
|----------------------------|--------------------------|-----|-----------------------------------|---------------------|----------------------|---------------------|------------|------------|----------------------|---------------------|----------------------|---------------------|----------------------|---------------------|---------------------------------|---------------------|----------------------|
|                            |                          |     | Peripherals disabled <sup>6</sup> | Peripherals enabled | Peripherals disabled | Peripherals enabled |            |            | Peripherals disabled | Peripherals enabled | Peripherals disabled | Peripherals enabled | Peripherals disabled | Peripherals enabled | Peripherals disabled            | Peripherals enabled |                      |
| MWCT1014 S                 | 25                       | Typ | 29                                | 42                  | 1.9                  | 2.5                 | TBD        | TBD        | TBD                  | TBD                 | TBD                  | TBD                 | TBD                  | TBD                 | TBD                             | TBD                 | TBD                  |
|                            | 105                      | Typ | TBD                               | TBD                 | TBD                  | TBD                 | TBD        | TBD        | TBD                  | TBD                 | TBD                  | TBD                 | 48                   | 57                  | 65                              | 75                  | TBD                  |
|                            |                          | Max | TBD                               | TBD                 | TBD                  | TBD                 | TBD        | TBD        | TBD                  | TBD                 | TBD                  | TBD                 | TBD                  | TBD                 | TBD                             | 90                  | TBD                  |
|                            | 125                      | Max | TBD                               | TBD                 | TBD                  | TBD                 | TBD        | TBD        | TBD                  | TBD                 | TBD                  | TBD                 | TBD                  | 67                  | NA                              | NA                  | TBD                  |
| MWCT1015 S                 | 25                       | Typ | TBD                               | TBD                 | TBD                  | TBD                 | TBD        | TBD        | TBD                  | TBD                 | TBD                  | TBD                 | TBD                  | TBD                 | TBD                             | TBD                 | TBD                  |
|                            | 105                      | Typ | TBD                               | TBD                 | TBD                  | TBD                 | TBD        | TBD        | TBD                  | TBD                 | TBD                  | TBD                 | TBD                  | TBD                 | TBD                             | TBD                 | TBD                  |
|                            |                          | Max | TBD                               | TBD                 | TBD                  | TBD                 | TBD        | TBD        | TBD                  | TBD                 | TBD                  | TBD                 | TBD                  | TBD                 | TBD                             | TBD                 | TBD                  |
|                            | 125                      | Max | TBD                               | TBD                 | TBD                  | TBD                 | TBD        | TBD        | TBD                  | TBD                 | TBD                  | TBD                 | TBD                  | TBD                 | NA                              | NA                  | TBD                  |
| MWCT1016 S <sup>7, 8</sup> | 25                       | Typ | 40                                | 60                  | 5                    | 6                   | TBD        | TBD        | TBD                  | TBD                 | TBD                  | TBD                 | TBD                  | TBD                 | TBD                             | TBD                 | TBD                  |
|                            | 105                      | Typ | TBD                               | TBD                 | TBD                  | TBD                 | TBD        | TBD        | TBD                  | TBD                 | TBD                  | TBD                 | TBD                  | TBD                 | TBD                             | TBD                 | TBD                  |
|                            |                          | Max | TBD                               | TBD                 | TBD                  | TBD                 | TBD        | TBD        | TBD                  | TBD                 | TBD                  | TBD                 | TBD                  | TBD                 | 125                             | 125                 | TBD                  |
|                            | 125                      | Max | TBD                               | TBD                 | TBD                  | TBD                 | TBD        | TBD        | TBD                  | TBD                 | TBD                  | TBD                 | 110                  | 110                 | NA                              | NA                  | TBD                  |

1. Typical current numbers are indicative for typical silicon process and may vary based on the silicon distribution and user configuration.
2. This is an average based on the use case described in the Comparator section, whereby the analog sampling is taking place periodically, with a mechanism to only enable the DAC as required. The numbers quoted assumes that only a single ANLCMP is active and the others are disabled

3. Current numbers are for reduced configuration and may vary based on user configuration and silicon process variation.
4. HSRUN mode must not be used at 125°C. Max ambient temperature for HSRUN mode is 105°C
5. Values mentioned are measured at 25 °C
6. With PMC\_REGSC[CLKBIASDIS] set to 1. See Reference Manual for details.
7. Above MWCT1016S data is preliminary targets only
8. The MWCT1016S data points assume that ENET/QuadSPI/SAI etc. are active. If the same configuration is selected as per the MWCT1014S, then the two devices will have very similar IDD.

### 4.7.1 Modes configuration

Attached *MWCT101xS\_Power\_Modes\_Configuration.xlsx* details the modes used in gathering the power consumption data stated in the above table [Table 7](#). For full functionality refer to table: Module operation in available low power modes of the *Reference Manual*.

## 4.8 ESD handling ratings

| Symbol    | Description                                           | Min.   | Max. | Unit | Notes             |
|-----------|-------------------------------------------------------|--------|------|------|-------------------|
| $V_{HBM}$ | Electrostatic discharge voltage, human body model     | – 4000 | 4000 | V    | <a href="#">1</a> |
| $V_{CDM}$ | Electrostatic discharge voltage, charged-device model |        |      |      | <a href="#">2</a> |
|           | All pins except the corner pins                       | – 500  | 500  | V    |                   |
|           | Corner pins only                                      | – 750  | 750  | V    |                   |
| $I_{LAT}$ | Latch-up current at ambient temperature of 125 °C     | – 100  | 100  | mA   | <a href="#">3</a> |

1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
2. Determined according to JEDEC Standard JESD22-C101, *Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components*.
3. Determined according to JEDEC Standard JESD78, *IC Latch-Up Test*.

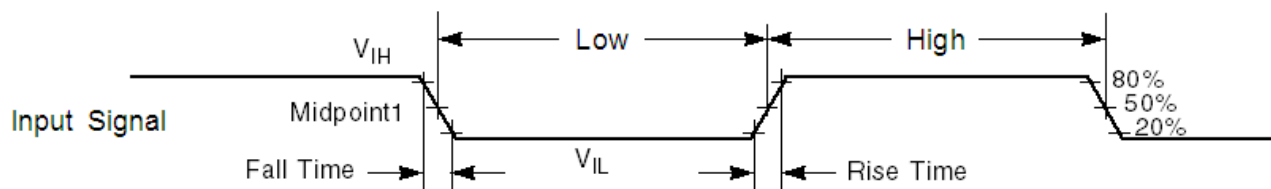
## 4.9 EMC radiated emissions operating behaviors

EMC measurements to IC-level IEC standards are available from NXP on request.

# 5 I/O parameters

## 5.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.



The midpoint is  $V_{IL} + (V_{IH} - V_{IL})/2$ .

**Figure 6. Input signal measurement reference**

## 5.2 General AC specifications

These general purpose specifications apply to all signals configured for GPIO, UART, and timers.

**Table 8. General switching specifications**

| Symbol | Description                                                                                                  | Min. | Max. | Unit             | Notes |
|--------|--------------------------------------------------------------------------------------------------------------|------|------|------------------|-------|
|        | GPIO pin interrupt pulse width (digital glitch filter disabled) — Synchronous path                           | 1.5  | —    | Bus clock cycles | 1, 2  |
|        | GPIO pin interrupt pulse width (digital glitch filter disabled, passive filter disabled) — Asynchronous path | 50   | —    | ns               | 3     |
| WFRST  | RESET input filtered pulse                                                                                   | —    | 100  | ns               | 4     |
| WFRST  | RESET input not filtered pulse                                                                               | 100  | —    | ns               |       |

1. This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In Stop and VLPS modes, the synchronizer is bypassed so shorter pulses can be recognized in that case.
2. The greater of synchronous and asynchronous timing must be met.
3. These pins do not have a passive filter on the inputs. This is the shortest pulse width that is guaranteed to be recognized.
4. Minimum length of RESET pulse, guaranteed not to be filtered by the internal filter.

## 5.3 DC electrical specifications at 3.3 V Range

**Table 9. DC electrical specifications at 3.3 V Range**

| Symbol       | Parameter                                                              | Value                |      |                     | Unit | Notes |
|--------------|------------------------------------------------------------------------|----------------------|------|---------------------|------|-------|
|              |                                                                        | Min.                 | Typ. | Max.                |      |       |
| $V_{DD}$     | I/O Supply Voltage                                                     | 2.7                  | 3.3  | 4                   | V    | 1     |
| $V_{ih}$     | Input Buffer High Voltage                                              | $0.7 \times V_{DD}$  | —    | $V_{DD} + 0.3$      | V    | 2     |
| $V_{il}$     | Input Buffer Low Voltage                                               | $V_{SS} - 0.3$       | —    | $0.3 \times V_{DD}$ | V    | 3     |
| $V_{hys}$    | Input Buffer Hysteresis                                                | $0.06 \times V_{DD}$ | —    | —                   | V    |       |
| Ioh_Standard | I/O current source capability measured when pad = ( $V_{DDE} - 0.8$ V) | 3.5                  | —    | —                   | mA   |       |

Table continues on the next page...

**Table 9. DC electrical specifications at 3.3 V Range (continued)**

| Symbol          | Parameter                                                                      | Value |       |      | Unit       | Notes |
|-----------------|--------------------------------------------------------------------------------|-------|-------|------|------------|-------|
|                 |                                                                                | Min.  | Typ.  | Max. |            |       |
| Iol_Standard    | I/O current sink capability measured when pad = 0.8 V                          | 3     | —     | —    | mA         |       |
| Ioh_Strong      | I/O current source capability measured when pad = ( $V_{DDE} - 0.8$ V)         | 14    | —     | —    | mA         | 4     |
| Iol_Strong      | I/O current sink capability measured when pad = 0.8 V                          | 12    | —     | —    | mA         | 5     |
| IOHT            | Output high current total for all ports                                        | —     | —     | 100  | mA         |       |
| IIN             | Input leakage current (per pin) for full temperature range at $V_{DD} = 3.3$ V |       |       |      |            | 6     |
|                 | All pins other than high drive port pins                                       |       | 0.005 | 0.5  | $\mu$ A    |       |
|                 | High drive port pins <sup>7</sup>                                              |       | 0.010 | 0.5  | $\mu$ A    |       |
| R <sub>PU</sub> | Internal pullup resistors                                                      | 20    |       | 60   | k $\Omega$ | 8     |
| R <sub>PD</sub> | Internal pulldown resistors                                                    | 20    |       | 60   | k $\Omega$ | 9     |

1. MWCT1016S will operate from 2.7 V when executing from internal FIRC. When the PLL is engaged MWCT1016S is guaranteed to operate from 2.97 V. All other MWCT101xS family devices operate from 2.7 V in all modes.
2. For reset pads, same  $V_{ih}$  levels are applicable
3. For reset pads, same  $V_{il}$  levels are applicable
4. The value given is measured at high drive strength mode. For value at low drive strength mode see the Ioh\_Standard value given above.
5. The value given is measured at high drive strength mode. For value at low drive strength mode see the Iol\_Standard value given above.
6. Several I/O have both high drive and normal drive capability selected by the associated Portx\_PCRn[DSE] control bit. All other GPIOs are normal drive only. For details refer to *MWCT101xS\_IO\_Signal\_Description\_Input\_Multiplexing.xlsx* attached with the *Reference Manual*.
7. When using ENET and SAI on MWCT1016S, the overall device limits associated with high drive pin configurations must be respected i.e. On 144-pin LQFP the general purpose pins: PTA10, PTD0, and PTE4 must be set to low drive.
8. Measured at input  $V = V_{SS}$
9. Measured at input  $V = V_{DD}$

## 5.4 DC electrical specifications at 5.0 V Range

**Table 10. DC electrical specifications at 5.0 V Range**

| Symbol       | Parameter                                                              | Value                |      |                      | Unit | Notes |
|--------------|------------------------------------------------------------------------|----------------------|------|----------------------|------|-------|
|              |                                                                        | Min.                 | Typ. | Max.                 |      |       |
| $V_{DD}$     | I/O Supply Voltage                                                     | 4                    | —    | 5.5                  | V    |       |
| $V_{ih}$     | Input Buffer High Voltage                                              | $0.65 \times V_{DD}$ | —    | $V_{DD} + 0.3$       | V    | 1     |
| $V_{il}$     | Input Buffer Low Voltage                                               | $V_{SS} - 0.3$       | —    | $0.35 \times V_{DD}$ | V    | 2     |
| $V_{hys}$    | Input Buffer Hysteresis                                                | $0.06 \times V_{DD}$ | —    | —                    | V    |       |
| Ioh_Standard | I/O current source capability measured when pad = ( $V_{DDE} - 0.8$ V) | 5                    | —    | —                    | mA   |       |
| Iol_Standard | I/O current sink capability measured when pad = 0.8 V                  | 5                    | —    | —                    | mA   |       |

Table continues on the next page...

**Table 10. DC electrical specifications at 5.0 V Range (continued)**

| Symbol          | Parameter                                                                             | Value |       |      | Unit          | Notes |
|-----------------|---------------------------------------------------------------------------------------|-------|-------|------|---------------|-------|
|                 |                                                                                       | Min.  | Typ.  | Max. |               |       |
| Ioh_Strong      | I/O current source capability measured when pad = $V_{DDE} - 0.8\text{ V}$            | 20    | —     | —    | mA            | 3, 4  |
| Iol_Strong      | I/O current sink capability measured when pad = 0.8 V                                 | 20    | —     | —    | mA            | 4, 5  |
| IOHT            | Output high current total for all ports                                               | —     | —     | 100  | mA            |       |
| IIN             | Input leakage current (per pin) for full temperature range at $V_{DD} = 5.5\text{ V}$ |       |       |      |               | 6     |
|                 | All pins other than high drive port pins                                              |       | 0.005 | 0.5  | $\mu\text{A}$ |       |
|                 | High drive port pins                                                                  |       | 0.010 | 0.5  | $\mu\text{A}$ |       |
| R <sub>PU</sub> | Internal pullup resistors                                                             | 20    |       | 50   | k $\Omega$    | 7     |
| R <sub>PD</sub> | Internal pulldown resistors                                                           | 20    |       | 50   | k $\Omega$    | 8     |

- For reset pads, same  $V_{ih}$  levels are applicable
- For reset pads, same  $V_{il}$  levels are applicable
- The value given is measured at high drive strength mode. For value at low drive strength mode see the Ioh\_Standard value given above.
- The strong pad I/O pin is capable of switching a 50 pF load at up to 40 MHz.
- The value given is measured at high drive strength mode. For value at low drive strength mode see the Iol\_Standard value given above.
- Several I/O have both high drive and normal drive capability selected by the associated Portx\_PCRn[DSE] control bit. All other GPIOs are normal drive only. For details refer to *MWCT101xS\_IO\_Signal\_Description\_Input\_Multiplexing.xlsx* attached with the *Reference Manual*.
- Measured at input  $V = V_{SS}$
- Measured at input  $V = V_{DD}$

## 5.5 AC electrical specifications at 3.3 V range

**Table 11. AC electrical specifications at 3.3 V Range**

| Symbol   | DSE | Rise time (nS) <sup>1</sup> |      | Fall time (nS) <sup>1</sup> |      | Capacitance (pF) <sup>2</sup> |
|----------|-----|-----------------------------|------|-----------------------------|------|-------------------------------|
|          |     | Min.                        | Max. | Min.                        | Max. |                               |
| Standard | NA  | 4.6                         | 14.5 | 3.9                         | 15.7 | 25                            |
|          |     | 7.2                         | 23.7 | 6.2                         | 26.2 | 50                            |
|          |     | 24.0                        | 75.4 | 20.8                        | 88.4 | 200                           |
| Strong   | 0   | 4.6                         | 14.5 | 3.9                         | 15.7 | 25                            |
|          |     | 7.2                         | 23.7 | 6.2                         | 26.2 | 50                            |
|          |     | 24.0                        | 75.4 | 20.8                        | 88.4 | 200                           |
|          | 1   | 2.0                         | 5.8  | 1.8                         | 6.1  | 25                            |
|          |     | 2.8                         | 8.0  | 2.6                         | 8.3  | 50                            |
|          |     | 7.0                         | 20.7 | 6.0                         | 22.4 | 200                           |

- For reference only. Run simulations with the IBIS model and your custom board for accurate results.
- Maximum capacitances supported on Standard IOs. However interface or protocol specific specifications might be different, for example for ENET, QSPI etc. . For protocol specific AC specifications, see respective sections.

## 5.6 AC electrical specifications at 5 V range

Table 12. AC electrical specifications at 5 V Range

| Symbol   | DSE | Rise time (nS) <sup>1</sup> |       | Fall time (nS) <sup>1</sup> |      | Capacitance (pF) <sup>2</sup> |
|----------|-----|-----------------------------|-------|-----------------------------|------|-------------------------------|
|          |     | Min.                        | Max . | Min.                        | Max. |                               |
| Standard | NA  | 3.2                         | 9.4   | 3.6                         | 10.7 | 25                            |
|          |     | 5.4                         | 15.7  | 5.1                         | 17.4 | 50                            |
|          |     | 18.5                        | 52.6  | 17.6                        | 59.7 | 200                           |
| Strong   | 0   | 4.0                         | 9.4   | 3.6                         | 10.7 | 25                            |
|          |     | 5.8                         | 15.7  | 5.1                         | 17.4 | 50                            |
|          |     | 18.1                        | 52.6  | 17.6                        | 59.7 | 200                           |
|          | 1   | 1.6                         | 4.6   | 1.5                         | 5.0  | 25                            |
|          |     | 2.2                         | 5.7   | 2.2                         | 5.8  | 50                            |
|          |     | 5.6                         | 14.6  | 5.0                         | 15.4 | 200                           |

1. For reference only. Run simulations with the IBIS model and your custom board for accurate results.
2. Maximum capacitances supported on Standard IOs. However interface or protocol specific specifications might be different, for example for ENET, QSPI etc. . For protocol specific AC specifications, see respective sections.

## 5.7 Standard input pin capacitance

Table 13. Standard input pin capacitance

| Symbol            | Description                     | Min. | Max. | Unit |
|-------------------|---------------------------------|------|------|------|
| C <sub>IN_A</sub> | Input capacitance: analog pins  | —    | 7    | pF   |
| C <sub>IN_D</sub> | Input capacitance: digital pins | —    | 7    | pF   |

### NOTE

Please refer to [External System Oscillator electrical specifications](#) for EXTAL/XTAL pins.

## 5.8 Device clock specifications

Table 14. Device clock specifications **1**

| Symbol                           | Description           | Min. | Max. | Unit |
|----------------------------------|-----------------------|------|------|------|
| High Speed run mode <sup>2</sup> |                       |      |      |      |
| f <sub>SYS</sub>                 | System and core clock | —    | 112  | MHz  |
| f <sub>BUS</sub>                 | Bus clock             | —    | 56   | MHz  |
| f <sub>FLASH</sub>               | Flash clock           | —    | 28   | MHz  |

Table continues on the next page...

**Table 14. Device clock specifications 1 (continued)**

| Symbol                                          | Description              | Min. | Max.  | Unit |
|-------------------------------------------------|--------------------------|------|-------|------|
| Normal run mode (MWCT101xS series) <sup>3</sup> |                          |      |       |      |
| f <sub>SYS</sub>                                | System and core clock    | —    | 80    | MHz  |
| f <sub>BUS</sub>                                | Bus clock                | —    | 40    | MHz  |
| f <sub>FLASH</sub>                              | Flash clock              | —    | 26.67 | MHz  |
| VLPR mode <sup>4</sup>                          |                          |      |       |      |
| f <sub>SYS</sub>                                | System and core clock    | —    | 4     | MHz  |
| f <sub>BUS</sub>                                | Bus clock                | —    | 4     | MHz  |
| f <sub>FLASH</sub>                              | Flash clock              | —    | 1     | MHz  |
| f <sub>ERCLK</sub>                              | External reference clock | —    | 16    | MHz  |

1. Refer to the section [Feature comparison](#) for the availability of modes and other specifications.
2. Only available on some devices. See section [Feature comparison](#).
3. With SPLP as system clock source.
4. The frequency limitations in VLPR mode here override any frequency specification listed in the timing specification for any other module.

## 6 Peripheral operating requirements and behaviors

### 6.1 System modules

There are no electrical specifications necessary for the device's system modules.

### 6.2 Clock interface modules

#### 6.2.1 External System Oscillator electrical specifications

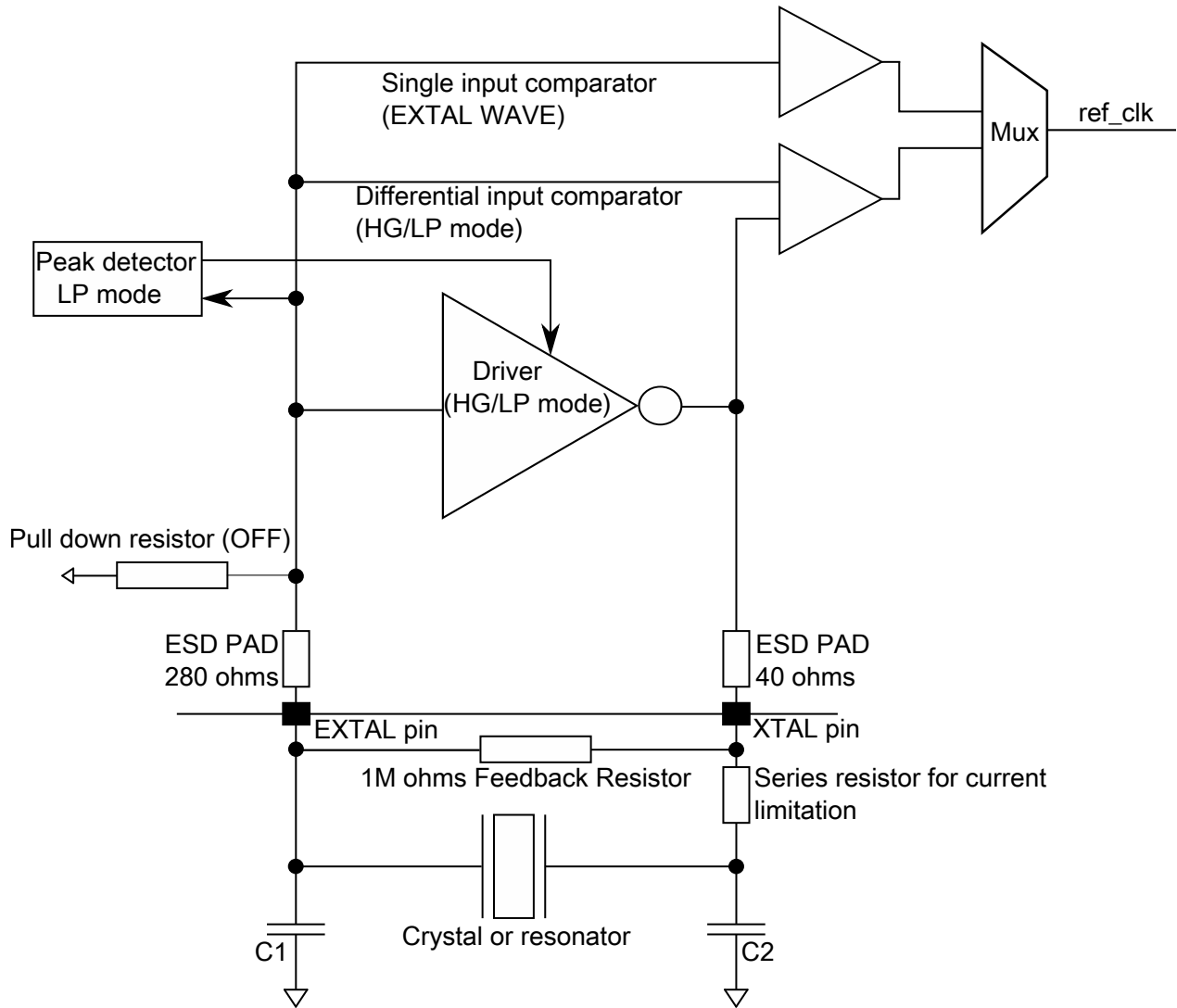


Figure 7. Oscillator connections scheme

Table 15. External System Oscillator electrical specifications

| Symbol             | Description                             | Min. | Typ. | Max. | Unit | Notes |
|--------------------|-----------------------------------------|------|------|------|------|-------|
| I <sub>DDOSC</sub> | Supply current — low-gain mode (HGO=0)  |      |      |      |      | 1     |
|                    | 4 MHz                                   | —    | 250  | —    | μA   |       |
|                    | 8 MHz                                   | —    | 350  | —    | μA   |       |
|                    | 16 MHz                                  | —    | 1.2  | —    | mA   |       |
|                    | 24 MHz                                  | —    | 1.6  | —    | mA   |       |
|                    | 32 MHz                                  | —    | 2    | —    | mA   |       |
|                    | 40 MHz                                  | —    | 2.6  | —    | mA   |       |
| I <sub>DDOSC</sub> | Supply current — high-gain mode (HGO=1) |      |      |      |      | 1     |
|                    | 4 MHz                                   | —    | 1    | —    | mA   |       |

Table continues on the next page...

**Table 15. External System Oscillator electrical specifications  
(continued)**

| Symbol             | Description                                             | Min.                  | Typ. | Max.                   | Unit | Notes |
|--------------------|---------------------------------------------------------|-----------------------|------|------------------------|------|-------|
|                    | 8 MHz                                                   | —                     | 1.2  | —                      | mA   |       |
|                    | 16 MHz                                                  | —                     | 3.5  | —                      | mA   |       |
|                    | 24 MHz                                                  | —                     | 5    | —                      | mA   |       |
|                    | 32 MHz                                                  | —                     | 5.5  | —                      | mA   |       |
|                    | 40 MHz                                                  | —                     | 6    | —                      | mA   |       |
| g <sub>mXOSC</sub> | Fast external crystal oscillator transconductance       |                       |      |                        |      |       |
|                    | 4-8 MHz                                                 | 2.2                   | —    | 9.7                    | mA/V |       |
|                    | 8-40 MHz                                                | 16                    | —    | 37                     | mA/V |       |
| V <sub>IL</sub>    | Input low voltage — EXTAL pin in external clock mode    | V <sub>SS</sub>       | —    | 0.35 * V <sub>DD</sub> | V    |       |
| V <sub>IH</sub>    | Input high voltage — EXTAL pin in external clock mode   | 0.7 * V <sub>DD</sub> | —    | V <sub>DD</sub>        | V    |       |
| C <sub>1</sub>     | EXTAL load capacitance                                  | —                     | —    | —                      |      | 2     |
| C <sub>2</sub>     | XTAL load capacitance                                   | —                     | —    | —                      |      | 2     |
| R <sub>F</sub>     | Feedback resistor                                       |                       |      |                        |      | 3     |
|                    | Low-gain mode (HGO=0)                                   | —                     | —    | —                      | MΩ   |       |
|                    | High-gain mode (HGO=1)                                  | —                     | 1    | —                      | MΩ   |       |
| R <sub>S</sub>     | Series resistor                                         |                       |      |                        |      |       |
|                    | Low-gain mode (HGO=0)                                   | —                     | 0    | —                      | kΩ   |       |
|                    | High-gain mode (HGO=1)                                  | —                     | 0    | —                      | kΩ   |       |
| V <sub>pp</sub>    | Peak-to-peak amplitude of oscillation (oscillator mode) |                       |      |                        |      | 4     |
|                    | Low-gain mode (HGO=0)                                   | —                     | 1.0  | —                      | V    |       |
|                    | High-gain mode (HGO=1)                                  | —                     | 3.3  | —                      | V    |       |

1. Measured at V<sub>DD</sub> = 5 V, Temperature = 25 °C
2. Crystal oscillator circuit provides stable oscillations when g<sub>mXOSC</sub> > 5 \* gm<sub>crit</sub>. The gm<sub>crit</sub> is defined as:

$$gm_{crit} = 4 * ESR * (2\pi F)^2 * (C_0 + C_L)^2$$

where:

- g<sub>mXOSC</sub> is the transconductance of the internal oscillator circuit
- ESR is the equivalent series resistance of the external crystal
- F is the external crystal oscillation frequency
- C<sub>0</sub> is the shunt capacitance of the external crystal
- C<sub>L</sub> is the external crystal total load capacitance.  $C_L = C_s + [C_1 * C_2 / (C_1 + C_2)]$
- C<sub>s</sub> is stray or parasitic capacitance on the pin due to any PCB traces
- C<sub>1</sub>, C<sub>2</sub> external load capacitances on EXTAL and XTAL pins

See manufacture datasheet for external crystal component values

3.
  - When low-gain is selected, internal R<sub>F</sub> will be selected and external R<sub>F</sub> should not be attached.
  - When high-gain is selected, external R<sub>F</sub> (1 M Ohm) needs to be connected for proper operation of the crystal. For external resistor, up to 5% tolerance is allowed.
4. The EXTAL and XTAL pins should only be connected to required oscillator components and must not be connected to any other devices.

## 6.2.2 External System Oscillator frequency specifications

Table 16. External System Oscillator frequency specifications

| Symbol          | Description                                  | Min. | Typ. | Max. | Unit | Notes |
|-----------------|----------------------------------------------|------|------|------|------|-------|
| $f_{osc\_hi}$   | Oscillator crystal or resonator frequency    | 4    | —    | 40   | MHz  |       |
| $f_{ec\_extal}$ | Input clock frequency (external clock mode)  | —    | —    | 50   | MHz  |       |
| $t_{dc\_extal}$ | Input clock duty cycle (external clock mode) | 40   | 50   | 60   | %    |       |
| $t_{cst}$       | Crystal Start-up Time                        |      |      |      |      |       |
|                 | 8 MHz low-gain mode (HGO=0)                  | —    | 1.5  | —    | ms   | 1     |
|                 | 8 MHz high-gain mode (HGO=1)                 | —    | 2.5  | —    |      |       |
|                 | 40 MHz low-gain mode (HGO=0)                 | —    | 2    | —    |      |       |
|                 | 40 MHz high-gain mode (HGO=1)                | —    | 2    | —    |      |       |

1. Proper PC board layout procedures must be followed to achieve specifications.

## 6.2.3 System Clock Generation (SCG) specifications

### 6.2.3.1 Fast internal RC Oscillator (FIRC) electrical specifications

Table 17. Fast internal RC Oscillator electrical specifications

| Symbol           | Parameter <sup>1</sup>                                       | Value |           |         | Unit         |
|------------------|--------------------------------------------------------------|-------|-----------|---------|--------------|
|                  |                                                              | Min.  | Typ.      | Max.    |              |
| $F_{FIRC}$       | FIRC target frequency                                        | —     | 48        | —       | MHz          |
| $I_{DDFIRC}^{2}$ | Supply current                                               | —     | 400       | 500     | $\mu A$      |
| $\Delta F$       | Frequency deviation across process, voltage, and temperature | —     | $\pm 0.5$ | $\pm 1$ | $\%F_{FIRC}$ |
| $T_{Startup}$    | Startup time                                                 |       | 3.4       | 5       | $\mu s^3$    |
| $T_{JIT}^{4}$    | Cycle-to-Cycle jitter                                        | —     | 250       | 500     | ps           |
| $T_{JIT}^{4}$    | Long term jitter over 1000 cycles                            | —     | 0.04      | 0.1     | $\%F_{FIRC}$ |

1. With FIRC regulator enable
2. Represents FIRC analog IP contribution. Additional current will be expected depending upon device configuration. See Power Management chapter of Reference Manual for the complete mode current consumption.
3. Startup time is defined as the time between clock enablement and clock availability for system use.
4. FIRC as system clock

### NOTE

Fast internal RC Oscillator is compliant with CAN and LIN standards.

### 6.2.3.2 Slow internal RC oscillator (SIRC) electrical specifications

**Table 18. Slow internal RC oscillator (SIRC) electrical specifications**

| Symbol          | Parameter                                                    | Value |      |         | Unit         |
|-----------------|--------------------------------------------------------------|-------|------|---------|--------------|
|                 |                                                              | Min.  | Typ. | Max.    |              |
| $F_{SIRC}$      | SIRC target frequency                                        | —     | 8    | —       | MHz          |
| $I_{DD SIRC}^1$ | Supply current                                               | —     | 25   | 35      | $\mu A$      |
| $\Delta F$      | Frequency deviation across process, voltage, and temperature | —     | —    | $\pm 3$ | $\%F_{SIRC}$ |
| $T_{Startup}$   | Startup time                                                 | —     | 9    | 12.5    | $\mu s^2$    |

1. Represents SIRC analog IP contribution. Additional current will be expected depending upon device configuration. See Power Management chapter of Reference Manual for the complete mode current consumption.
2. Startup time is defined as the time between clock enablement and clock availability for system use.

### 6.2.4 Low Power Oscillator (LPO) electrical specifications

**Table 19. Low Power Oscillator (LPO) electrical specifications**

| Symbol        | Parameter                               | Min. | Typ. | Max. | Unit    |
|---------------|-----------------------------------------|------|------|------|---------|
| $F_{LPO}$     | Internal low power oscillator frequency | 113  | 128  | 139  | kHz     |
| $I_{LPO}$     | Current consumption                     | 1    | 3    | TBD  | $\mu A$ |
| $T_{startup}$ | Startup Time                            | —    | —    | 20   | $\mu s$ |

### 6.2.5 SPLL electrical specifications

**Table 20. SPLL electrical specifications**

| Symbol              | Parameter                                                                                                           | Min. | Typ. | Max. | Unit |
|---------------------|---------------------------------------------------------------------------------------------------------------------|------|------|------|------|
| $F_{SPLL\_REF}^1$   | PLL Reference Frequency Range                                                                                       | 8    | —    | 16   | MHz  |
| $F_{SPLL\_Input}^2$ | PLL Input Frequency                                                                                                 | 8    | —    | 40   | MHz  |
| $F_{VCO\_CLK}$      | VCO output frequency                                                                                                | 180  | —    | 320  | MHz  |
| $F_{SPLL\_CLK}$     | PLL output frequency                                                                                                | 90   | —    | 160  | MHz  |
| $I_{DD SPLL}$       | PLL operating current <sup>3</sup>                                                                                  |      |      |      |      |
|                     | $F_{VCO\_CLK}$ @ 320 MHz ( $F_{SPLL\_Input}$ = 16 MHz, MULT = 20, PREDIV = 1, generating $F_{SPLL\_CLK}$ @ 160 MHz) | —    | 2.2  | —    | mA   |
|                     | $F_{VCO\_CLK}$ @ 224 MHz ( $F_{SPLL\_Input}$ = 32 MHz, MULT = 21, PREDIV = 3, generating $F_{SPLL\_CLK}$ @ 112 MHz) | —    | 1.6  | —    | mA   |
| $J_{CYC\_SPLL}$     | PLL Period Jitter (RMS) <sup>4</sup>                                                                                |      |      |      |      |
|                     | at $F_{VCO\_CLK}$ 180 MHz                                                                                           | —    | 120  | —    | ps   |
|                     | at $F_{VCO\_CLK}$ 320 MHz                                                                                           | —    | 75   | —    | ps   |

Table continues on the next page...

**Table 20. SPLL electrical specifications  
(continued)**

| Symbol                 | Parameter                                          | Min.   | Typ. | Max.                                                       | Unit |
|------------------------|----------------------------------------------------|--------|------|------------------------------------------------------------|------|
| J <sub>ACC_SPLL</sub>  | PLL accumulated jitter over 1µs (RMS) <sup>4</sup> |        |      |                                                            |      |
|                        | at F <sub>VCO_CLK</sub> 180 MHz                    | —      | 1350 | —                                                          | ps   |
|                        | at F <sub>VCO_CLK</sub> 320 MHz                    | —      | 600  | —                                                          | ps   |
| D <sub>UNL</sub>       | Lock exit frequency tolerance                      | ± 4.47 | —    | ± 5.97                                                     | %    |
| T <sub>SPLL_LOCK</sub> | Lock detector detection time <sup>5</sup>          | —      | —    | 150 × 10 <sup>-6</sup> +<br>1075(1/F <sub>SPLL_REF</sub> ) | s    |

1. F<sub>SPLL\_REF</sub> is PLL reference frequency range after the PREDIV. For PREDIV and MULT settings refer SCG\_SPLLCFG register of Reference Manual.
2. F<sub>SPLL\_Input</sub> is PLL input frequency range before the PREDIV must be limited to the range 8 MHz to 40 MHz. This input source could be derived from a crystal oscillator or some other external square wave clock source using OSC bypass mode. For external clock source settings refer SCG\_SOSCCFG register of Reference Manual.
3. Excludes any oscillator currents that are also consuming power while PLL is in operation.
4. This specification was obtained using a NXP developed PCB. PLL jitter is dependent on the noise characteristics of each PCB and results will vary
5. This specification applies to any time the PLL VCO divider or reference divider is changed, or changing from PLL disabled (BLPE, BLPI) to PLL enabled (PBE, PEE). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

## 6.3 Memory and memory interfaces

### 6.3.1 Flash memory module (FTFC) electrical specifications

This section describes the electrical characteristics of the flash memory module.

#### 6.3.1.1 Flash timing specifications — commands

**Table 21. Flash command timing specifications**

| Symbol                  | Description <sup>1</sup>                     | Min. | Typ. | Max. | Unit | Notes |
|-------------------------|----------------------------------------------|------|------|------|------|-------|
| t <sub>rd1blk64k</sub>  | Read 1s Block execution time                 | —    | —    | 0.5  | ms   |       |
| t <sub>rd1blk512k</sub> | • 64 KB data flash<br>• 512 KB program flash | —    | —    | 1.8  | ms   |       |
| t <sub>rd1sec2k</sub>   | Read 1s Section execution time (2 KB flash)  | —    | —    | 75   | µs   |       |
| t <sub>rd1sec4k</sub>   | Read 1s Section execution time (4 KB flash)  | —    | —    | 100  | µs   |       |
| t <sub>pgmchk</sub>     | Program Check execution time                 | —    | —    | 95   | µs   |       |
| t <sub>pgm8</sub>       | Program Phrase execution time                | —    | 90   | 150  | µs   |       |
| t <sub>ersblk64k</sub>  | Erase Flash Block execution time             | —    | 55   | 475  | ms   | 2     |
| t <sub>ersblk512k</sub> | • 64 KB data flash<br>• 512 KB program flash | —    | 435  | 3700 | ms   |       |

Table continues on the next page...

**Table 21. Flash command timing specifications (continued)**

| Symbol                  | Description <sup>1</sup>                                                                                                                              | Min. | Typ. | Max. | Unit | Notes |
|-------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|------|-------|
| t <sub>ersscr</sub>     | Erase Flash Sector execution time                                                                                                                     | —    | 15   | 115  | ms   | 2     |
| t <sub>pgmsec1k</sub>   | Program Section execution time (1KB flash)                                                                                                            | —    | 5    | —    | ms   |       |
| t <sub>rd1allx</sub>    | Read 1s All Blocks execution time                                                                                                                     | —    | —    | 2.2  | ms   |       |
| t <sub>rdonce</sub>     | Read Once execution time                                                                                                                              | —    | —    | 30   | μs   |       |
| t <sub>pgmonce</sub>    | Program Once execution time                                                                                                                           | —    | 90   | —    | μs   |       |
| t <sub>ersall</sub>     | Erase All Blocks execution time                                                                                                                       | —    | 500  | 4200 | ms   | 2     |
| t <sub>vfykey</sub>     | Verify Backdoor Access Key execution time                                                                                                             | —    | —    | 30   | μs   |       |
| t <sub>ersallu</sub>    | Erase All Blocks Unsecure execution time                                                                                                              | —    | 500  | 4200 | ms   | 2     |
| t <sub>pgmpart32k</sub> | Program Partition for EEPROM execution time                                                                                                           | —    | 70   | —    | ms   | 3, 4  |
| t <sub>pgmpart64k</sub> | • 32 KB EEPROM backup<br>• 64 KB EEPROM backup                                                                                                        | —    | 71   | —    | ms   |       |
| t <sub>setramff</sub>   | Set FlexRAM Function execution time:                                                                                                                  | —    | 70   | —    | μs   | 3, 4  |
| t <sub>setram32k</sub>  | • Control Code 0xFF                                                                                                                                   | —    | 0.8  | 1.2  | ms   |       |
| t <sub>setram48k</sub>  | • 32 KB EEPROM backup                                                                                                                                 | —    | 1.0  | 1.5  | ms   |       |
| t <sub>setram64k</sub>  | • 48 KB EEPROM backup<br>• 64 KB EEPROM backup                                                                                                        | —    | 1.3  | 1.9  | ms   |       |
| t <sub>eewr8b32k</sub>  | Byte-write to FlexRAM execution time:                                                                                                                 | —    | 385  | 1700 | μs   | 3, 4  |
| t <sub>eewr8b48k</sub>  | • 32 KB EEPROM backup                                                                                                                                 | —    | 430  | 1850 | μs   |       |
| t <sub>eewr8b64k</sub>  | • 48 KB EEPROM backup<br>• 64 KB EEPROM backup                                                                                                        | —    | 475  | 2000 | μs   |       |
| t <sub>eewr16b32k</sub> | 16-bit write to FlexRAM execution time:                                                                                                               | —    | 385  | 1700 | μs   | 3, 4  |
| t <sub>eewr16b48k</sub> | • 32 KB EEPROM backup                                                                                                                                 | —    | 430  | 1850 | μs   |       |
| t <sub>eewr16b64k</sub> | • 48 KB EEPROM backup<br>• 64 KB EEPROM backup                                                                                                        | —    | 475  | 2000 | μs   |       |
| t <sub>eewr32bers</sub> | 32-bit write to erased FlexRAM location execution time                                                                                                | —    | 360  | 2000 | μs   | 4     |
| t <sub>eewr32b32k</sub> | 32-bit write to FlexRAM execution time:                                                                                                               | —    | 630  | 2000 | μs   | 3, 4  |
| t <sub>eewr32b48k</sub> | • 32 KB EEPROM backup                                                                                                                                 | —    | 720  | 2125 | μs   |       |
| t <sub>eewr32b64k</sub> | • 48 KB EEPROM backup<br>• 64 KB EEPROM backup                                                                                                        | —    | 810  | 2250 | μs   |       |
| t <sub>quickwr</sub>    | 32-bit Quick Write execution time : Time from CCIF clearing (start the write) until CCIF setting (32-bit write complete, ready for next 32-bit write) |      |      |      |      |       |
|                         | • 1st 32-bit write                                                                                                                                    | —    | —    | 200  | μs   | 5, 6  |
|                         | • 2nd through Next to Last (Nth-1) 32-bit write                                                                                                       | —    | —    | 150  | μs   |       |
|                         | • Last (Nth) 32-bit write (time for write only, not cleanup)                                                                                          | —    | —    | 200  | μs   |       |

Table continues on the next page...

**Table 21. Flash command timing specifications (continued)**

| Symbol                    | Description <sup>1</sup>           | Min. | Typ. | Max.                           | Unit | Notes |
|---------------------------|------------------------------------|------|------|--------------------------------|------|-------|
| t <sub>quickwrClnup</sub> | Quick Write Cleanup execution time | —    | —    | (Number of Quick Writes) * 2.0 | ms   | 7     |

1. All command times assumes 25 MHz or greater flash clock frequency (for synchronization time between internal/external clocks).
2. Maximum times for erase parameters based on expectations at cycling end-of-life.
3. For all EEPROM Emulation terms, the specified timing shown assumes previous record clean up has occurred. This may be verified by executing FCCOB Command 0x77, and checking FCCOB number 5 contents show 0x00 - No EEPROM issues detected.
4. 'First time' EERAM writes after a POR or SETRAM may incur additional overhead for EEE cleanup, resulting in up to 2x the times shown.
5. Only after the Nth write completes will any data will be valid. Emulated EEPROM record scheme cleanup overhead may occur after this point even after a brownout or reset. If power or reset occurs before the Nth write completes, the last valid record set will still be valid and the new records will be discarded.
6. Additionally, one of the 1st through Nth Quick Write may take up to 400 uS (vs. the time in the table) as additional cleanup may occur when crossing sector boundaries.
7. Time for emulated EEPROM record scheme overhead cleanup. Automatically done after last (Nth) write completes, assuming still powered. Or via SetRAM cleanup execution command is requested at a later point.

### 6.3.1.2 Reliability specifications

**Table 22. NVM reliability specifications**

| Symbol                     | Description                                                                     | Min.  | Typ. | Max. | Unit   | Notes   |
|----------------------------|---------------------------------------------------------------------------------|-------|------|------|--------|---------|
| Program and Data Flash     |                                                                                 |       |      |      |        |         |
| t <sub>nvmretp1k</sub>     | Data retention after up to 1 K cycles                                           | 20    | —    | —    | years  |         |
| n <sub>nvmcycp</sub>       | Cycling endurance                                                               | 1 K   | —    | —    | cycles | 1       |
| FlexRAM as Emulated EEPROM |                                                                                 |       |      |      |        |         |
| t <sub>nvmreteee</sub>     | Data retention                                                                  | 5     | —    | —    | years  |         |
| n <sub>nvmwree16</sub>     | Write endurance                                                                 | 100 K | —    | —    | writes | 2, 3, 4 |
| n <sub>nvmwree256</sub>    | • EEPROM backup to FlexRAM ratio = 16<br>• EEPROM backup to FlexRAM ratio = 256 | 1.6 M | —    | —    | writes |         |

1. Program and erase supported across standard temperature specifications.
2. EEE write endurance specified for 16-bit and/or 32-bit writes to FlexRAM and is supported across standard temperature specs. Greater EEE write endurance achieved with larger ratios of EEPROM backup to FlexRAM used.
3. Any other EEE driver usage will result in w/e endurance specification of Native D-Flash (1 K)
4. [EEE calculator tool](#) is available at NXP web site to help estimate the maximum write endurance achievable at specific EEPROM/FlexRAM ratio. The "In Spec" portions of the online calculator refer to the NVM reliability specifications section of data sheet.

### 6.3.2 QuadSPI AC specifications

The following table describes the QuadSPI electrical characteristics.

- Measurements are with maximum output load of 25 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).

- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN ), the interface should be OFF.
- Add 50 ohm series termination on board in QuadSPI SCK for Flash A to avoid loop back reflection when using in Internal DQS (PAD Loopback) mode.
- For non-Quad mode of operation if external device doesn't have pull-up feature, external pull-up needs to be added at board level for non-used pads.
- With external pull-up, performance of the interface may degrade based on load associated with external pull-up.

Table 23. QuadSPI electrical specifications

| FLASH PORT             | Sym              | Unit | FLASH A            |     |                    |     |                    |     |                    |     |                    |     |                    |     | FLASH B                |     |                   |                 |
|------------------------|------------------|------|--------------------|-----|--------------------|-----|--------------------|-----|--------------------|-----|--------------------|-----|--------------------|-----|------------------------|-----|-------------------|-----------------|
|                        |                  |      | RUN <sup>1</sup>   |     |                    |     |                    |     | HSRUN <sup>1</sup> |     |                    |     |                    |     | RUN/HSRUN <sup>2</sup> |     |                   |                 |
| QuadSPI Mode           |                  |      | SDR                |     |                    |     |                    |     | SDR                |     |                    |     |                    |     | SDR                    |     | DDR <sup>3</sup>  |                 |
|                        |                  |      | Internal Sampling  |     | Internal DQS       |     |                    |     | Internal Sampling  |     | Internal DQS       |     |                    |     | Internal Sampling      |     | External DQS      |                 |
|                        |                  |      | N1                 |     | PAD Loopback       |     | Internal Loopback  |     | N1                 |     | PAD Loopback       |     | Internal Loopback  |     | N1                     |     | Extrenal DQS      |                 |
|                        |                  |      | Min                | Max | Min                | Max | Min                | Max | Min                | Max | Min                | Max | Min                | Max | Min                    | Max | Min               | Max             |
| Register Settings      |                  |      |                    |     |                    |     |                    |     |                    |     |                    |     |                    |     |                        |     |                   |                 |
| MCR[DDR_EN]            |                  | -    | 0                  |     | 0                  |     | 0                  |     | 0                  |     | 0                  |     | 0                  |     | 0                      |     | 1                 |                 |
| MCR[DQS_EN]            |                  | -    | 0                  |     | 1                  |     | 1                  |     | 0                  |     | 1                  |     | 1                  |     | 0                      |     | 1                 |                 |
| MCR[SCLKCFG[0]]        |                  | -    | -                  |     | 1                  |     | 0                  |     | -                  |     | 1                  |     | 0                  |     | -                      |     | -                 |                 |
| MCR[SCLKCFG[1]]        |                  | -    | -                  |     | 1                  |     | 0                  |     | -                  |     | 1                  |     | 0                  |     | -                      |     | -                 |                 |
| MCR[SCLKCFG[2]]        |                  | -    | -                  |     | -                  |     | -                  |     | -                  |     | -                  |     | -                  |     | -                      |     | 0                 |                 |
| MCR[SCLKCFG[3]]        |                  | -    | -                  |     | -                  |     | -                  |     | -                  |     | -                  |     | -                  |     | -                      |     | 0                 |                 |
| MCR[SCLKCFG[5]]        |                  | -    | -                  |     | -                  |     | -                  |     | -                  |     | -                  |     | -                  |     | -                      |     | 1                 |                 |
| SMPR[FSPHS]            |                  | -    | 0                  |     | 1                  |     | 0                  |     | 0                  |     | 1                  |     | 0                  |     | 0                      |     | 0                 |                 |
| SMPR[FSDLY]            |                  | -    | 0                  |     | 0                  |     | 0                  |     | 0                  |     | 0                  |     | 0                  |     | 0                      |     | 0                 |                 |
| SOCCR<br>[SOCCFG[7:0]] |                  |      | -                  |     | 0                  |     | 23                 |     | -                  |     | 0                  |     | 30                 |     | -                      |     | -                 |                 |
| SOCCR[SOCCFG[15:8]]    |                  | -    | -                  |     | -                  |     | -                  |     | -                  |     | -                  |     | -                  |     | -                      |     | 30                |                 |
| FLSHCR[TDH]            |                  | -    | 0x00               |     | 0x00               |     | 0x00               |     | 0x00               |     | 0x00               |     | 0x00               |     | 0x00                   |     | 0x01              |                 |
| Timing Parameters      |                  |      |                    |     |                    |     |                    |     |                    |     |                    |     |                    |     |                        |     |                   |                 |
| SCK Clock Frequency    | f <sub>SCK</sub> | MHz  | -                  | 38  | -                  | 64  | -                  | 48  | -                  | 40  | -                  | 80  | -                  | 50  | -                      | 20  | -                 | 20 <sup>4</sup> |
| SCK Clock Period       | t <sub>SCK</sub> | ns   | 1/f <sub>SCK</sub> | -   | 1/f <sub>SCK</sub> | -   | 1/f <sub>SCK</sub> | -   | 1/f <sub>SCK</sub> | -   | 1/f <sub>SCK</sub> | -   | 1/f <sub>SCK</sub> | -   | 50.0                   | -   | 50.0 <sup>4</sup> | -               |

Table continues on the next page...

Table 23. QuadSPI electrical specifications (continued)

| FLASH PORT                  | Sym                | Unit | FLASH A                   |                           |                           |                           |                           |                           |                           |                           |                             |                             |                           |                           | FLASH B                   |                           |                           |                           |
|-----------------------------|--------------------|------|---------------------------|---------------------------|---------------------------|---------------------------|---------------------------|---------------------------|---------------------------|---------------------------|-----------------------------|-----------------------------|---------------------------|---------------------------|---------------------------|---------------------------|---------------------------|---------------------------|
|                             |                    |      | RUN <sup>1</sup>          |                           |                           |                           |                           |                           | HSRUN <sup>1</sup>        |                           |                             |                             |                           |                           | RUN/HSRUN <sup>2</sup>    |                           |                           |                           |
| QuadSPI Mode                |                    |      | SDR                       |                           |                           |                           |                           |                           | SDR                       |                           |                             |                             |                           |                           | SDR                       |                           | DDR <sup>3</sup>          |                           |
|                             |                    |      | Internal Sampling         |                           | Internal DQS              |                           |                           |                           | Internal Sampling         |                           | Internal DQS                |                             |                           |                           | Internal Sampling         |                           | External DQS              |                           |
|                             |                    |      | N1                        |                           | PAD Loopback              |                           | Internal Loopback         |                           | N1                        |                           | PAD Loopback                |                             | Internal Loopback         |                           | N1                        |                           | Extrenal DQS              |                           |
|                             |                    |      | Min                       | Max                       | Min                       | Max                       | Min                       | Max                       | Min                       | Max                       | Min                         | Max                         | Min                       | Max                       | Min                       | Max                       | Min                       | Max                       |
| SCK Duty Cycle              | t <sub>SDC</sub>   | ns   | t <sub>SCK</sub> /2 - 1.5 | t <sub>SCK</sub> /2 + 1.5 | t <sub>SCK</sub> /2 - 1.5 | t <sub>SCK</sub> /2 + 1.5 | t <sub>SCK</sub> /2 - 1.5 | t <sub>SCK</sub> /2 + 1.5 | t <sub>SCK</sub> /2 - 1.5 | t <sub>SCK</sub> /2 + 1.5 | t <sub>SCK</sub> /2 - 0.750 | t <sub>SCK</sub> /2 - 0.750 | t <sub>SCK</sub> /2 - 1.5 | t <sub>SCK</sub> /2 + 1.5 | t <sub>SCK</sub> /2 - 2.5 | t <sub>SCK</sub> /2 + 2.5 | t <sub>SCK</sub> /2 - 2.5 | t <sub>SCK</sub> /2 + 2.5 |
| Data Input Setup Time       | t <sub>IS</sub>    | ns   | 15                        | -                         | 2.5                       | -                         | 10                        | -                         | 14                        | -                         | 1.5                         | -                           | 9                         | -                         | 25                        | -                         | -2                        | -                         |
| Data Input Hold Time        | t <sub>IH</sub>    | ns   | 0                         | -                         | 1                         | -                         | 1                         | -                         | 0                         | -                         | 1                           | -                           | 1                         | -                         | 0                         | -                         | 0                         | -                         |
| Data Output Valid Time      | t <sub>OV</sub>    | ns   | -                         | 4.5                       | -                         | 4.5                       | -                         | 4.5                       | -                         | 4                         | -                           | 4                           | -                         | 4                         | -                         | 10                        | -                         | 10                        |
| Data Output In-Valid Time   | t <sub>IV</sub>    | ns   | 5                         | -                         | 5                         | -                         | 5                         | -                         | 5                         | -                         | 3 <sup>5</sup>              | -                           | 5                         | -                         | 5                         | -                         | 5                         | -                         |
| CS to SCK Time <sup>6</sup> | t <sub>CSSCK</sub> | ns   | 5                         | -                         | 5                         | -                         | 5                         | -                         | 5                         | -                         | 5                           | -                           | 5                         | -                         | 10                        | -                         | 10                        | -                         |
| SCK to CS Time <sup>7</sup> | t <sub>SCKCS</sub> | ns   | 5                         | -                         | 5                         | -                         | 5                         | -                         | 5                         | -                         | 5                           | -                           | 5                         | -                         | 5                         | -                         | 5                         | -                         |
| Output Load                 |                    | pf   | 25                        |                           | 25                        |                           | 25                        |                           | 25                        |                           | 25                          |                             | 25                        |                           | 25                        |                           | 25                        |                           |

1. See Reference Manual for details on mode settings
2. See Reference Manual for details on mode settings
3. Valid for HyperRAM only
4. RWDS(External DQS CLK) frequency
5. For operating frequency ≤ 64 Mhz, Output invalid time is 5 ns.
6. Program register value QuadSPI\_FLSHCR[TCSS] = 4'h2
7. Program register value QuadSPI\_FLSHCR[TCSH] = 4'h1

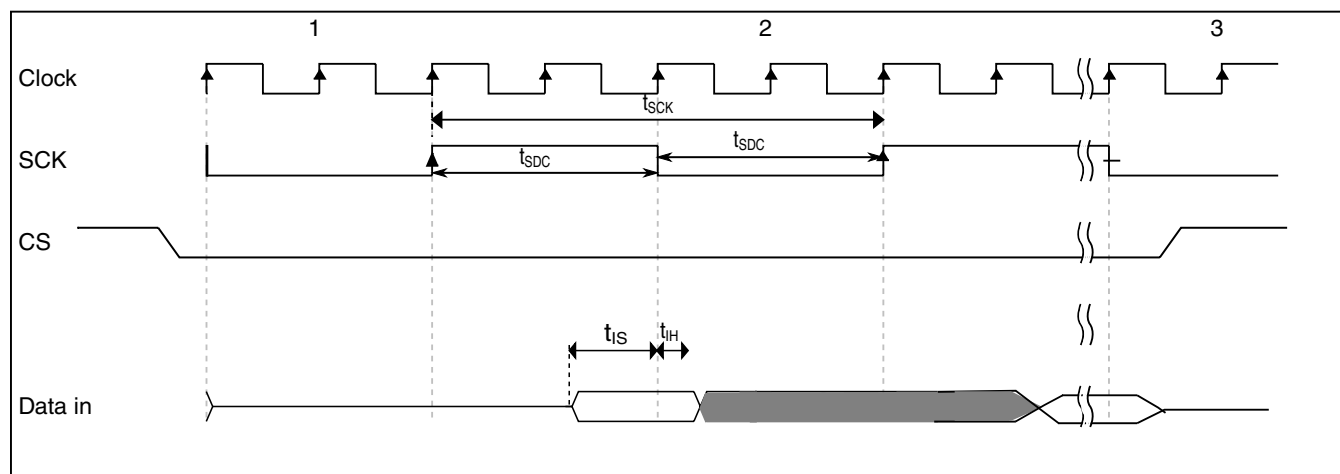


Figure 8. QuadSPI input timing (SDR mode) diagram

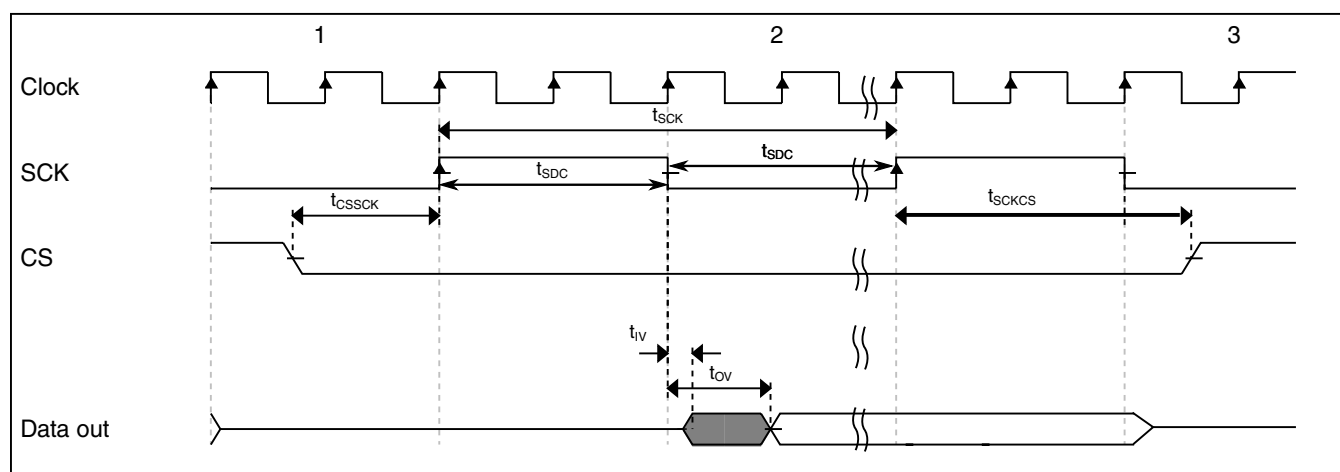


Figure 9. QuadSPI output timing (SDR mode) diagram

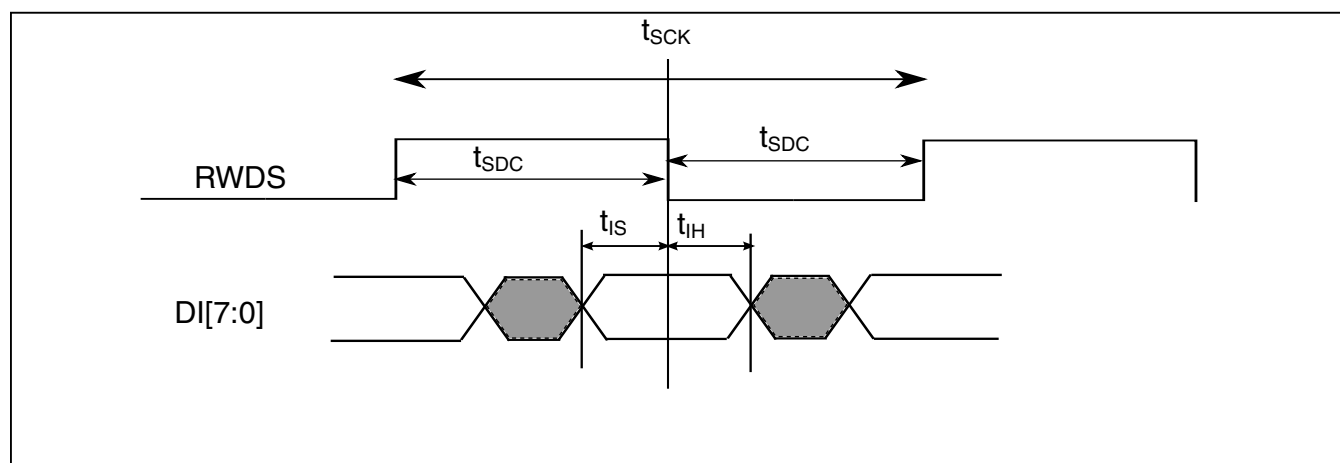


Figure 10. QuadSPI input timing (HyperRAM mode) diagram

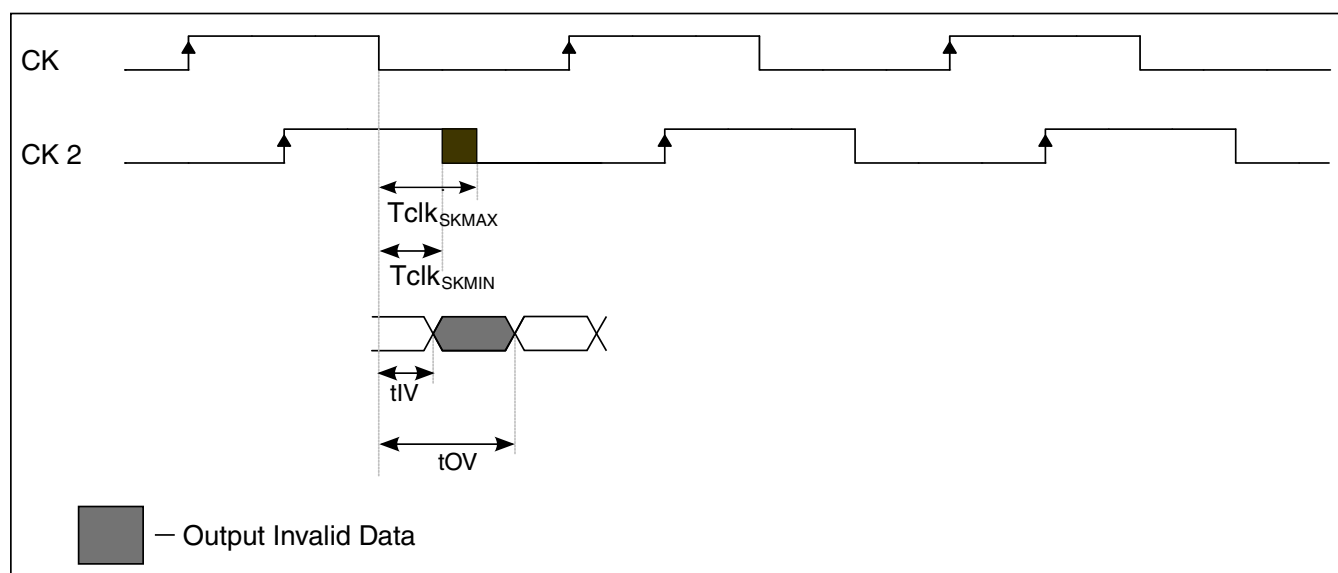


Figure 11. QuadSPI output timing (HyperRAM mode) diagram

## 6.4 Analog modules

### 6.4.1 ADC electrical specifications

#### 6.4.1.1 12-bit ADC operating conditions

Table 24. 12-bit ADC operating conditions

| Symbol           | Description                         | Conditions                               | Min.                                                                      | Typ. <sup>1</sup> | Max.                                                                      | Unit       | Notes |
|------------------|-------------------------------------|------------------------------------------|---------------------------------------------------------------------------|-------------------|---------------------------------------------------------------------------|------------|-------|
| $\Delta V_{DDA}$ | Supply voltage                      | Delta to $V_{DD}$ ( $V_{DD} - V_{DDA}$ ) | -0.1                                                                      | 0                 | +0.1                                                                      | V          | 2     |
| $V_{REFH}$       | ADC reference voltage high          |                                          | See <a href="#">Voltage and current operating requirements</a> for values | $V_{DDA}$         | See <a href="#">Voltage and current operating requirements</a> for values | V          | 3     |
| $V_{REFL}$       | ADC reference voltage low           |                                          | See <a href="#">Voltage and current operating requirements</a> for values | 0                 | See <a href="#">Voltage and current operating requirements</a> for values | mV         | 3     |
| $V_{ADIN}$       | Input voltage                       |                                          | $V_{REFL}$                                                                | —                 | $V_{REFH}$                                                                | V          |       |
| $C_{ADIN}$       | Input capacitance                   |                                          | —                                                                         | 4                 | 5                                                                         | pF         |       |
| $R_{ADIN}$       | Input series resistance             |                                          | —                                                                         | 2                 | 5                                                                         | k $\Omega$ |       |
| $R_{AS}$         | Analog source resistance (external) | $f_{ADCK} < 4$ MHz                       | —                                                                         | —                 | 5                                                                         | k $\Omega$ |       |
| $f_{ADCK}$       | ADC conversion clock frequency      | Normal usage                             | 2                                                                         | 40                | 50                                                                        | MHz        | 4, 5  |

Table continues on the next page...

Table 24. 12-bit ADC operating conditions (continued)

| Symbol            | Description         | Conditions                                                                                                | Min. | Typ. <sup>1</sup> | Max.  | Unit | Notes |
|-------------------|---------------------|-----------------------------------------------------------------------------------------------------------|------|-------------------|-------|------|-------|
| C <sub>rate</sub> | ADC conversion rate | No ADC hardware averaging. <sup>6</sup> Continuous conversions enabled, subsequent conversion time        | 46.4 | 928               | 1160  | Ksps | 7, 8  |
|                   |                     | ADC hardware averaging set to 32. <sup>6</sup> Continuous conversions enabled, subsequent conversion time | 1.45 | 29                | 36.25 | Ksps | 7, 8  |

1. Typical values assume  $V_{DDA} = 5\text{ V}$ ,  $\text{Temp} = 25\text{ }^{\circ}\text{C}$ ,  $f_{\text{ADCK}} = 40\text{ MHz}$ ,  $R_{\text{AS}} = 20\text{ }\Omega$ , and  $C_{\text{AS}} = 10\text{ nF}$  unless otherwise stated. Typical values are for reference only, and are not tested in production.
2. DC potential difference.
3. For packages without dedicated  $V_{\text{REFH}}$  and  $V_{\text{REFL}}$  pins,  $V_{\text{REFH}}$  is internally tied to  $V_{\text{DDA}}$ , and  $V_{\text{REFL}}$  is internally tied to  $V_{\text{SS}}$ . To get maximum performance, reference supply quality should be better than SAR ADC. See application note [AN5032](#) for details.
4. Clock and compare cycle need to be set according to the guidelines mentioned in the *Reference Manual*.
5. ADC conversion will become less reliable above maximum frequency.
6. When using ADC hardware averaging, see the *Reference Manual* to determine the most appropriate setting for AVGS.
7. Numbers based on the minimum sampling time of 275 ns.
8. For guidelines and examples of conversion rate calculation, see the *Reference Manual* or download the ADC calculator tool.

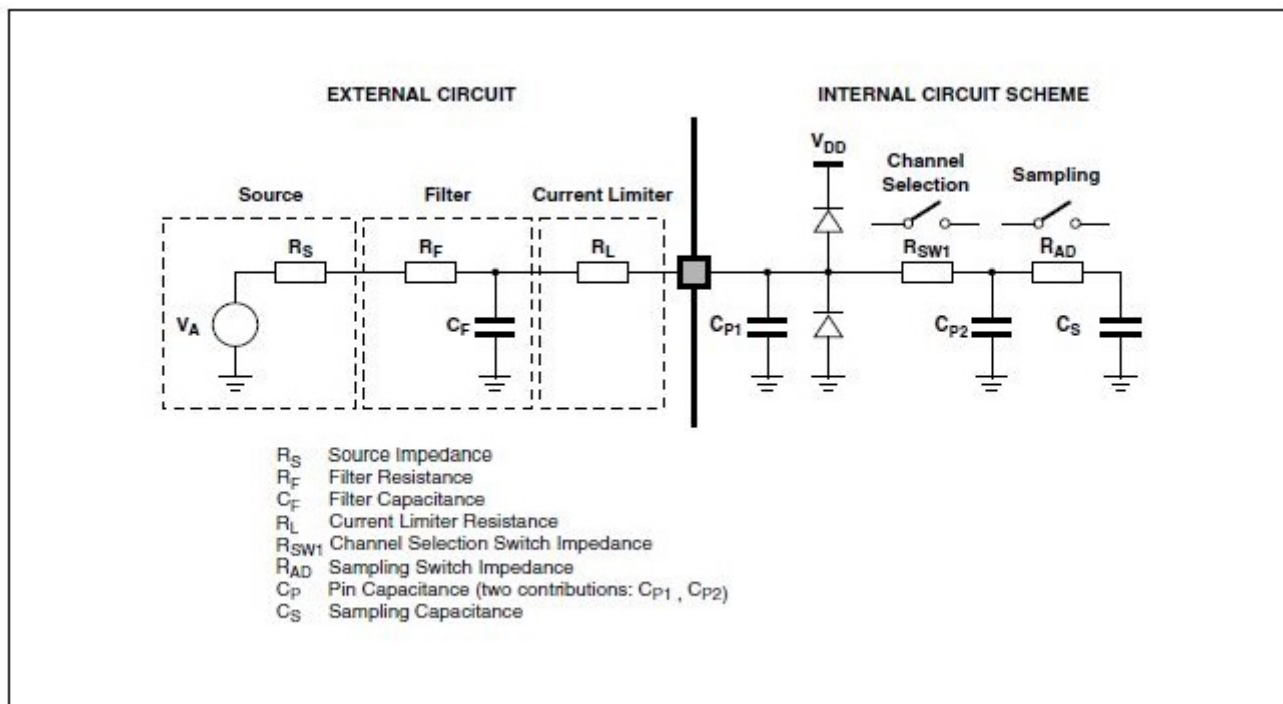


Figure 12. ADC input impedance equivalency diagram

### 6.4.1.2 12-bit ADC electrical characteristics

#### NOTE

ADC performance specifications are documented using a single ADC. For parallel/simultaneous operation of both ADCs, either for sampling the same channel by both ADCs or for sampling different channels by each ADC, some amount of decrease in performance can be expected. Care must be taken to stagger the two ADC conversions, in particular the sample phase, to minimize the impact of simultaneous conversions.

**Table 25. 12-bit ADC characteristics (2.7 V to 3 V) ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SS}$ ) <sup>1</sup>**

| Symbol           | Description                | Conditions <sup>2</sup> | Min. | Typ. <sup>3</sup> | Max.                                 | Unit             | Notes       |
|------------------|----------------------------|-------------------------|------|-------------------|--------------------------------------|------------------|-------------|
| $V_{DDA}$        | Supply voltage             |                         | 2.7  | —                 | 3                                    | V                |             |
| $I_{DDA\_ADC}$   | Supply current             |                         | TBD  | —                 | TBD                                  | mA               | 4           |
| SMPLTS           | Sample Time                |                         | TBD  | —                 | Refer to the <i>Reference Manual</i> | ns               |             |
| TUE <sup>5</sup> | Total unadjusted error     |                         | —    | TBD               | TBD                                  | LSB <sup>6</sup> | 7, 8, 9, 10 |
| DNL              | Differential non-linearity |                         | —    | TBD               | —                                    | LSB <sup>6</sup> | 7, 8, 9, 10 |
| INL              | Integral non-linearity     |                         | —    | TBD               | —                                    | LSB <sup>6</sup> | 7, 8, 9, 10 |

1. All the parameters in this table assume that XOSC is being used as the system clock source and ADC clock is derived from this source.
2. All accuracy numbers assume the ADC is calibrated with  $V_{REFH}=V_{DDA}=V_{DD}$ , with the calibration frequency set to half the ADC clock frequency.
3. Typical values assume  $V_{DDA} = \text{TBD}$ , Temp = 25 °C,  $f_{ADCK} = 40 \text{ MHz}$ ,  $R_{AS}=20 \Omega$ , and  $C_{AS}=10 \text{ nF}$  unless otherwise stated.
4. The ADC supply current depends on the ADC conversion rate.
5. Represents total static error, which includes offset and full scale error.
6.  $1 \text{ LSB} = (V_{REFH} - V_{REFL})/2^N$
7. The specifications are with averaging and in standalone mode only. Performance may degrade depending upon device use case scenario. When using ADC averaging, refer to the *Reference Manual* to determine the most appropriate settings for AVGS.
8. For ADC signals adjacent to  $V_{DD}/V_{SS}$  or XTAL/EXTAL or high frequency switching pins, some degradation in the ADC performance may be observed.
9. All values guarantee the performance of the ADC for multiple ADC input channel pins. When using ADC to monitor the internal analog parameters, assume minor degradation.
10. All the parameters in the table are given assuming system clock as the clocking source for ADC.

**Table 26. 12-bit ADC characteristics (3 V to 5.5 V)( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SS}$ ) <sup>1</sup>**

| Symbol         | Description    | Conditions <sup>2</sup> | Min. | Typ. <sup>3</sup> | Max.                                 | Unit | Notes |
|----------------|----------------|-------------------------|------|-------------------|--------------------------------------|------|-------|
| $V_{DDA}$      | Supply voltage |                         | 3    | —                 | 5.5                                  | V    |       |
| $I_{DDA\_ADC}$ | Supply current |                         | TBD  | —                 | TBD                                  | mA   | 4     |
| SMPLTS         | Sample Time    |                         | 275  | —                 | Refer to the <i>Reference Manual</i> | ns   |       |

Table continues on the next page...

**Table 26. 12-bit ADC characteristics (3 V to 5.5 V)( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SS}$ ) 1 (continued)**

| Symbol           | Description                | Conditions <sup>2</sup> | Min. | Typ. <sup>3</sup> | Max. | Unit             | Notes       |
|------------------|----------------------------|-------------------------|------|-------------------|------|------------------|-------------|
| TUE <sup>5</sup> | Total unadjusted error     |                         | —    | ±4                | TBD  | LSB <sup>6</sup> | 7, 8, 9, 10 |
| DNL              | Differential non-linearity |                         | —    | ±0.7              | —    | LSB <sup>6</sup> | 7, 8, 9, 10 |
| INL              | Integral non-linearity     |                         | —    | ±1.0              | —    | LSB <sup>6</sup> | 7, 8, 9, 10 |

1. All the parameters in this table assume that XOSC is being used as the system clock source and ADC clock is derived from this source.
2. All accuracy numbers assume the ADC is calibrated with  $V_{REFH}=V_{DDA}=V_{DD}$ , with the calibration frequency set to half the ADC clock frequency.
3. Typical values assume  $V_{DDA} = 5.0$  V, Temp = 25 °C,  $f_{ADCK} = 40$  MHz,  $R_{AS}=20$  Ω, and  $C_{AS}=10$  nF unless otherwise stated.
4. The ADC supply current depends on the ADC conversion rate.
5. Represents total static error, which includes offset and full scale error.
6. 1 LSB =  $(V_{REFH} - V_{REFL})/2^N$
7. The specifications are with averaging and in standalone mode only. Performance may degrade depending upon device use case scenario. When using ADC averaging, refer to the *Reference Manual* to determine the most appropriate settings for AVGS.
8. For ADC signals adjacent to  $V_{DD}/V_{SS}$  or XTAL/EXTAL or high frequency switching pins, some degradation in the ADC performance may be observed.
9. All values guarantee the performance of the ADC for multiple ADC input channel pins. When using ADC to monitor the internal analog parameters, assume minor degradation.
10. All the parameters in the table are given assuming system clock as the clocking source for ADC.

### NOTE

When using high speed interfaces such as the QuadSPI, SAI0, SAI1 or ENET there may be some ADC degradation on the adjacent analog input paths. See following table for details.

| Pin name | TGATE purpose      |
|----------|--------------------|
| PTE8     | CMP0_IN3           |
| PTC3     | ADC0_SE11/CMP0_IN4 |
| PTC2     | ADC0_SE10/CMP0_IN5 |
| PTD7     | CMP0_IN6           |
| PTD6     | CMP0_IN7           |
| PTD28    | ADC1_SE22          |
| PTD27    | ADC1_SE21          |

## 6.4.2 CMP with 8-bit DAC electrical specifications

**Table 28. Comparator with 8-bit DAC electrical specifications**

| Symbol      | Description                                  | Min. | Typ. | Max. | Unit |
|-------------|----------------------------------------------|------|------|------|------|
| $I_{DDHS}$  | Supply current, High-speed mode <sup>1</sup> |      |      |      | μA   |
|             | -40 - 125 °C                                 | —    | 230  | 300  |      |
| $I_{DDL S}$ | Supply current, Low-speed mode <sup>1</sup>  |      |      |      | μA   |
|             | -40 - 105 °C                                 | —    | 5    | 10   |      |

Table continues on the next page...

**Table 28. Comparator with 8-bit DAC electrical specifications (continued)**

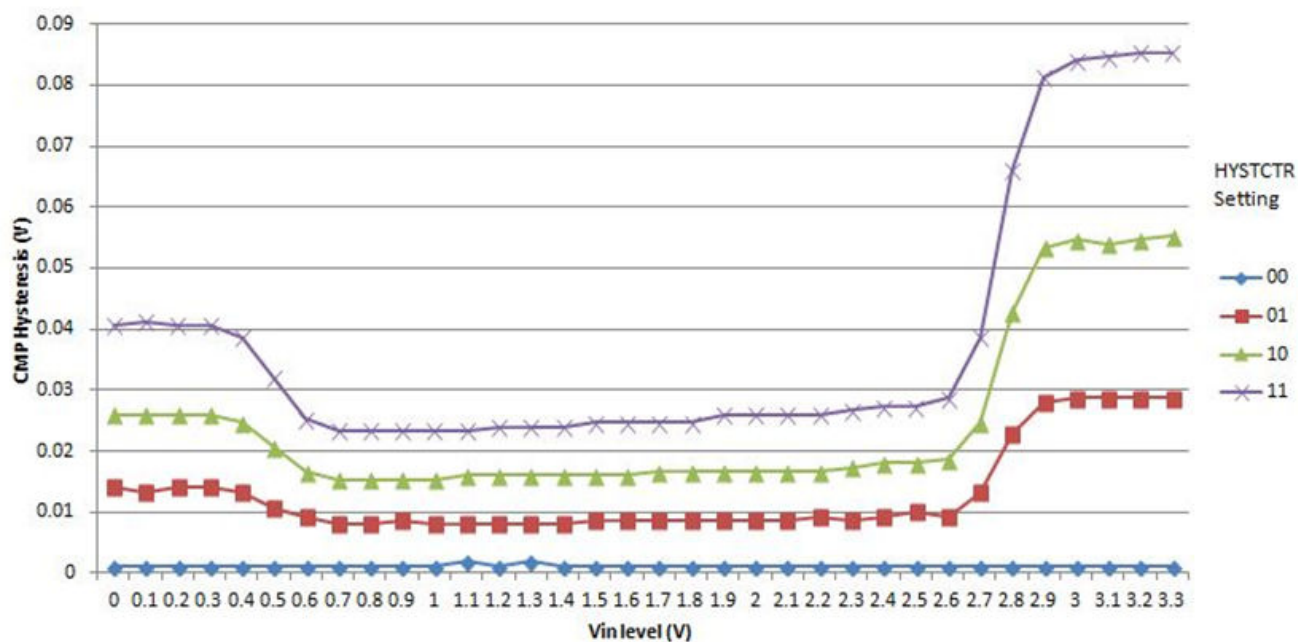
| Symbol             | Description                                             | Min. | Typ.                 | Max.             | Unit |
|--------------------|---------------------------------------------------------|------|----------------------|------------------|------|
|                    | -40 - 125 °C                                            |      | 5                    | 13               |      |
| V <sub>AIN</sub>   | Analog input voltage                                    | 0    | 0 - V <sub>DDA</sub> | V <sub>DDA</sub> | V    |
| V <sub>AIO</sub>   | Analog input offset voltage, High-speed mode            |      |                      |                  | mV   |
|                    | -40 - 125 °C                                            | -25  | ±1                   | 25               |      |
| V <sub>AIO</sub>   | Analog input offset voltage, Low-speed mode             |      |                      |                  | mV   |
|                    | -40 - 125 °C                                            | -40  | ±4                   | 40               |      |
| t <sub>DHSB</sub>  | Propagation delay, High-speed mode <sup>2</sup>         |      |                      |                  | ns   |
|                    | -40 - 105 °C                                            | —    | 30                   | 200              |      |
|                    | -40 - 125 °C                                            |      | 30                   | 300              |      |
| t <sub>DLSB</sub>  | Propagation delay, Low-speed mode <sup>2</sup>          |      |                      |                  | µs   |
|                    | -40 - 105 °C                                            | —    | 0.5                  | 2                |      |
|                    | -40 - 125 °C                                            | —    | 0.5                  | 3                |      |
| t <sub>DHSS</sub>  | Propagation delay, High-speed mode <sup>3</sup>         |      |                      |                  | ns   |
|                    | -40 - 105 °C                                            | —    | 70                   | 400              |      |
|                    | -40 - 125 °C                                            | —    | 70                   | 500              |      |
| t <sub>DLSS</sub>  | Propagation delay, Low-speed mode <sup>3</sup>          |      |                      |                  | µs   |
|                    | -40 - 105 °C                                            | —    | 1                    | 5                |      |
|                    | -40 - 125 °C                                            | —    | 1                    | 5                |      |
| t <sub>IDHS</sub>  | Initialization delay, High-speed mode <sup>4</sup>      |      |                      |                  | µs   |
|                    | -40 - 125 °C                                            | —    | 1.5                  | 3                |      |
| t <sub>IDLS</sub>  | Initialization delay, Low-speed mode <sup>4</sup>       |      |                      |                  | µs   |
|                    | -40 - 125 °C                                            | —    | 10                   | 30               |      |
| V <sub>HYST0</sub> | Analog comparator hysteresis, Hyst0 (V <sub>AIO</sub> ) |      |                      |                  | mV   |
|                    | -40 - 125 °C                                            | —    | 0                    | —                |      |
| V <sub>HYST1</sub> | Analog comparator hysteresis, Hyst1, High-speed mode    |      |                      |                  | mV   |
|                    | -40 - 125 °C                                            | —    | 16                   | 66               |      |
|                    | Analog comparator hysteresis, Hyst1, Low-speed mode     |      |                      |                  |      |
|                    | -40 - 125 °C                                            | —    | 11                   | 40               |      |
| V <sub>HYST2</sub> | Analog comparator hysteresis, Hyst2, High-speed mode    |      |                      |                  | mV   |
|                    | -40 - 125 °C                                            | —    | 32                   | 133              |      |
|                    | Analog comparator hysteresis, Hyst2, Low-speed mode     |      |                      |                  |      |
|                    | -40 - 125 °C                                            | —    | 22                   | 80               |      |
| V <sub>HYST3</sub> | Analog comparator hysteresis, Hyst3, High-speed mode    |      |                      |                  | mV   |
|                    | -40 - 125 °C                                            | —    | 48                   | 200              |      |
|                    | Analog comparator hysteresis, Hyst3, Low-speed mode     |      |                      |                  |      |

Table continues on the next page...

**Table 28. Comparator with 8-bit DAC electrical specifications (continued)**

| Symbol      | Description                                | Min.  | Typ. | Max. | Unit             |
|-------------|--------------------------------------------|-------|------|------|------------------|
|             | -40 - 125 °C                               | —     | 33   | 120  |                  |
| $I_{DAC8b}$ | 8-bit DAC current adder (enabled)          |       |      |      |                  |
|             | 3.3V Reference Voltage                     | —     | 6    | 9    | $\mu A$          |
|             | 5V Reference Voltage                       | —     | 10   | 16   | $\mu A$          |
| $INL^5$     | 8-bit DAC integral non-linearity           | -0.75 | —    | 0.75 | LSB <sup>6</sup> |
| $DNL$       | 8-bit DAC differential non-linearity       | -0.5  | —    | 0.5  | LSB <sup>6</sup> |
| $t_{DDAC}$  | Initialization and switching settling time | —     | —    | 30   | $\mu s$          |

1. Difference at input > 200mV
2. Applied  $\pm (100 \text{ mV} + V_{HYST0/1/2/3+ \text{ max. of } V_{AIO}})$  around switch point.
3. Applied  $\pm (30 \text{ mV} + 2 \times V_{HYST0/1/2/3+ \text{ max. of } V_{AIO}})$  around switch point.
4. Applied  $\pm (100 \text{ mV} + V_{HYST0/1/2/3})$ .
5. Calculation method used: Linear Regression Least Square Method
6.  $1 \text{ LSB} = V_{\text{reference}}/256$

**Figure 13. Typical hysteresis vs. Vin level (VDDA = 3.3 V, PMODE = 0)**

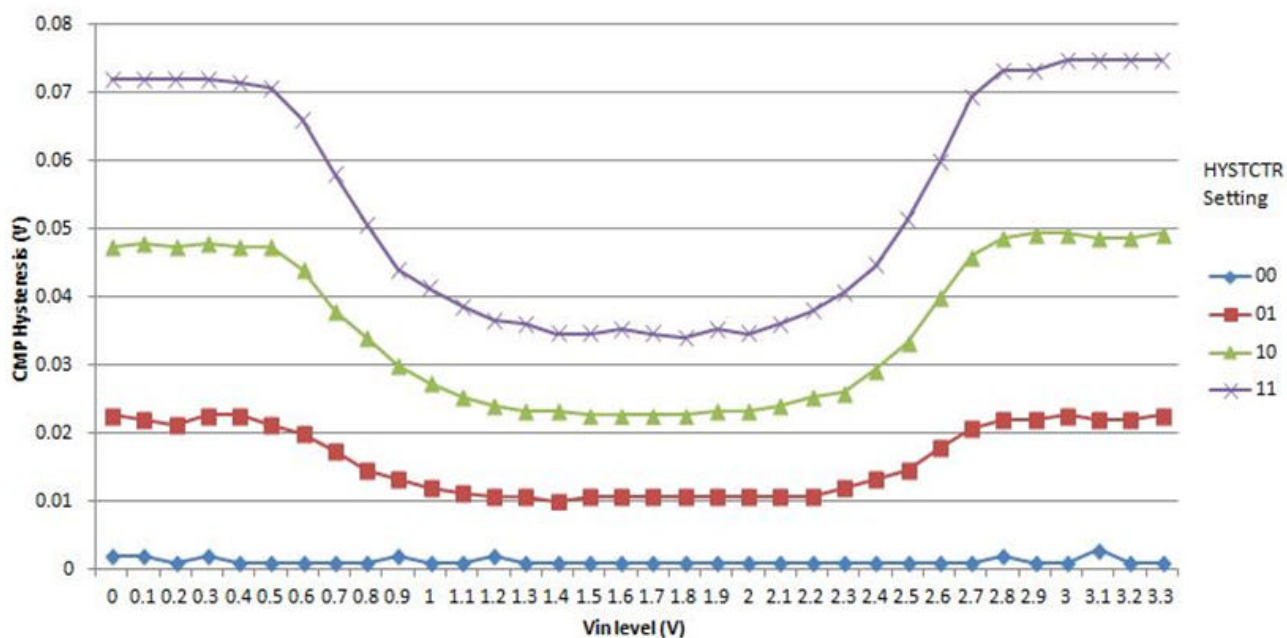


Figure 14. Typical hysteresis vs. Vin level (VDDA = 3.3 V, PMODE = 1)

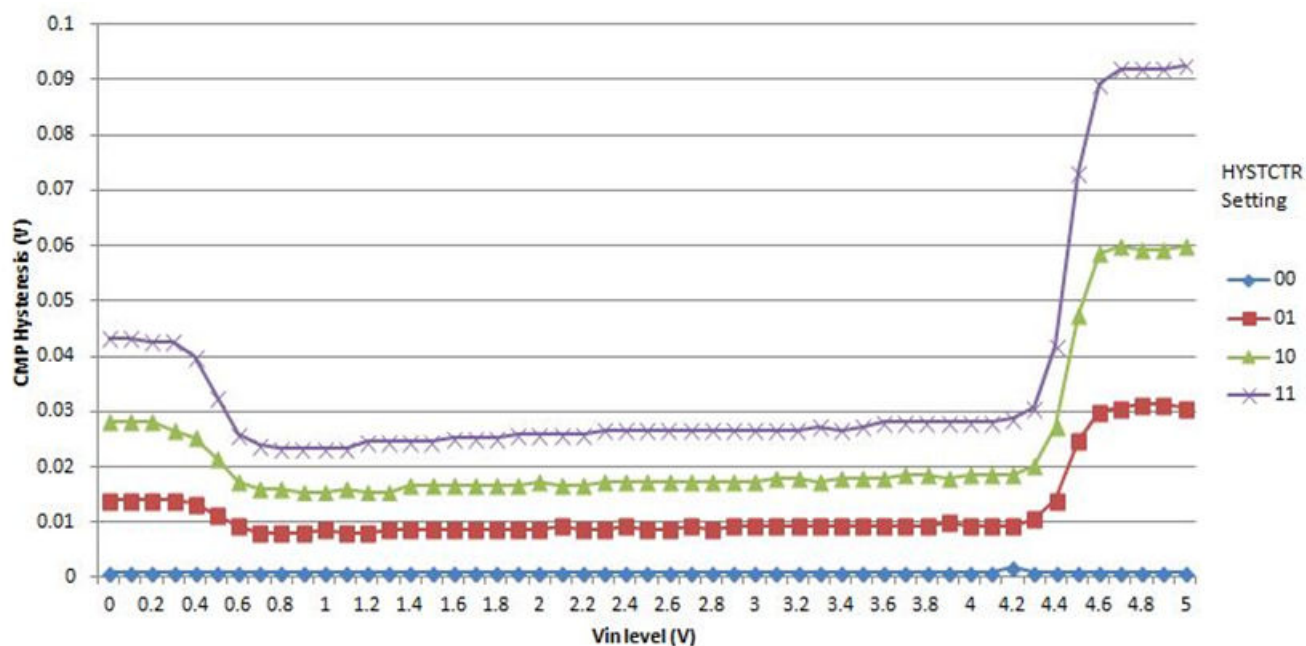


Figure 15. Typical hysteresis vs. Vin level (VDDA = 5 V, PMODE = 0)

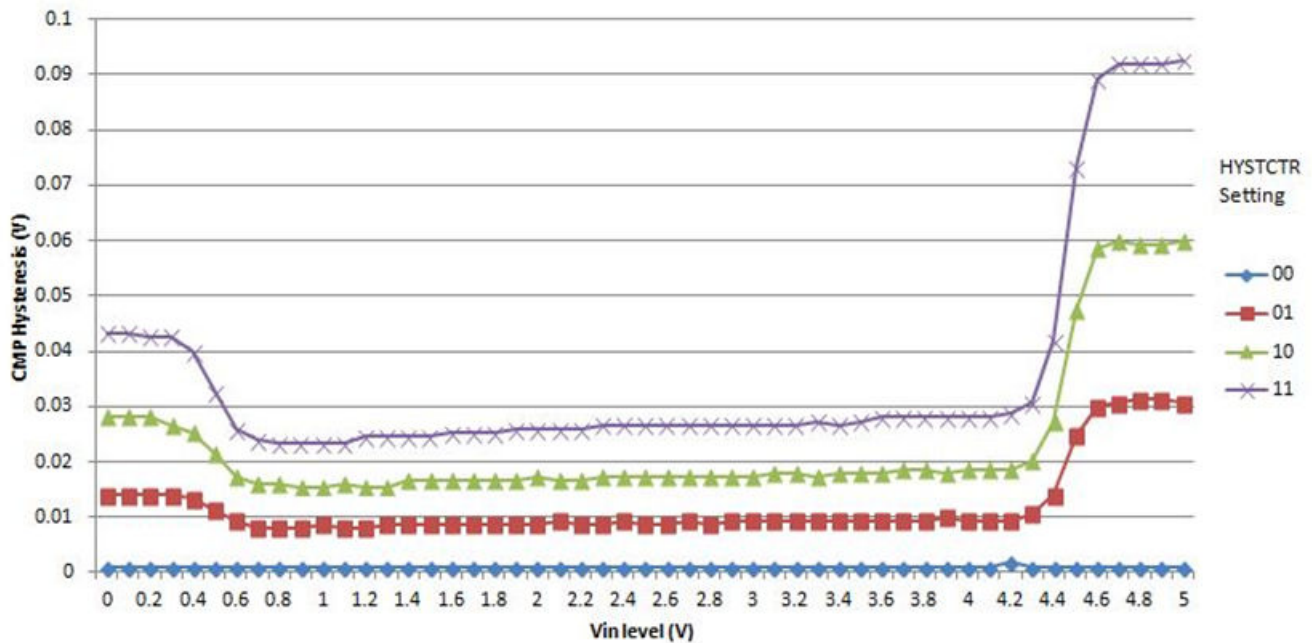


Figure 16. Typical hysteresis vs. Vin level (VDDA = 5 V, PMODE = 1)

## 6.5 Communication modules

### 6.5.1 LPUART electrical specifications

Refer to [General AC specifications](#) for LPUART specifications.

#### 6.5.1.1 Supported baud rate

Baud rate = Baud clock / ((OSR+1) \* SBR).

For details, see section: 'Baud rate generation' of the *Reference Manual*.

### 6.5.2 LPSPI electrical specifications

The Low Power Serial Peripheral Interface (LPSPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The following tables provide timing characteristics for classic LPSPI timing modes.

- All timing is shown with respect to 20%  $V_{DD}$  and 80%  $V_{DD}$  thresholds.
- All measurements are with maximum output load of 50 pF, input transition of 1 ns and pad configured with fastest slew setting ( DSE = 1 ).

Table 29. LPSPI electrical specifications<sup>1</sup>

| Num | Symbol                              | Description                           | Conditions                         | Run Mode <sup>2</sup> |      |          |      | HSRUN Mode <sup>2</sup> |      |          |      | VLPR Mode |      |          |      | Unit |
|-----|-------------------------------------|---------------------------------------|------------------------------------|-----------------------|------|----------|------|-------------------------|------|----------|------|-----------|------|----------|------|------|
|     |                                     |                                       |                                    | 5.0 V IO              |      | 3.3 V IO |      | 5.0 V IO                |      | 3.3 V IO |      | 5.0 V IO  |      | 3.3 V IO |      |      |
|     |                                     |                                       |                                    | Min.                  | Max. | Min.     | Max. | Min.                    | Max. | Min.     | Max. | Min.      | Max. | Min.     | Max. |      |
|     | f <sub>periph</sub> <sup>3, 4</sup> | Peripheral Frequency                  | Slave                              | -                     | 40   | -        | 40   | -                       | 56   | -        | 56   | -         | 8    | -        | 8    | MHz  |
|     |                                     |                                       | Master                             | -                     | 40   | -        | 40   | -                       | 56   | -        | 56   | -         | 8    | -        | 8    |      |
|     |                                     |                                       | Master Loopback <sup>5</sup>       | -                     | 40   | -        | 48   | -                       | 48   | -        | 48   | -         | 8    | -        | 8    |      |
|     |                                     |                                       | Master Loopback(Slow) <sup>6</sup> | -                     | 48   | -        | 48   | -                       | 48   | -        | 48   | -         | 8    | -        | 8    |      |
| 1   | f <sub>op</sub>                     | Frequency of operation                | Slave                              | -                     | 10   | -        | 10   | -                       | 14   | -        | 14   | -         | 4    | -        | 4    | MHz  |
|     |                                     |                                       | Master                             | -                     | 10   | -        | 10   | -                       | 14   | -        | 14   | -         | 4    | -        | 4    |      |
|     |                                     |                                       | Master Loopback <sup>5</sup>       | -                     | 20   | -        | 12   | -                       | 24   | -        | 12   | -         | 4    | -        | 4    |      |
|     |                                     |                                       | Master Loopback(slow) <sup>6</sup> | -                     | 12   | -        | 12   | -                       | 12   | -        | 12   | -         | 4    | -        | 4    |      |
| 2   | t <sub>SPSCK</sub>                  | SPSCK period                          | Slave                              | 100                   | -    | 100      | -    | 72                      | -    | 72       | -    | 250       | -    | 250      | -    | ns   |
|     |                                     |                                       | Master                             | 100                   | -    | 100      | -    | 72                      | -    | 72       | -    | 250       | -    | 250      | -    |      |
|     |                                     |                                       | Master Loopback <sup>5</sup>       | 50                    | -    | 83       | -    | 42                      | -    | 83       | -    | 250       | -    | 250      | -    |      |
|     |                                     |                                       | Master Loopback(slow) <sup>6</sup> | 83                    | -    | 83       | -    | 83                      | -    | 83       | -    | 250       | -    | 250      | -    |      |
| 3   | t <sub>Lead</sub> <sup>7</sup>      | Enable lead time (PCS to SPSCK delay) | Slave                              | -                     | -    | -        | -    | -                       | -    | -        | -    | -         | -    | -        | ns   |      |

Table continues on the next page...

Table 29. LPSPI electrical specifications<sup>1</sup> (continued)

| Num | Symbol                        | Description                         | Conditions                         | Run Mode <sup>2</sup>                |      |                                      |      | HSRUN Mode <sup>2</sup>              |      |                                      |      | VLPR Mode                            |      |                                      |      | Unit |
|-----|-------------------------------|-------------------------------------|------------------------------------|--------------------------------------|------|--------------------------------------|------|--------------------------------------|------|--------------------------------------|------|--------------------------------------|------|--------------------------------------|------|------|
|     |                               |                                     |                                    | 5.0 V IO                             |      | 3.3 V IO                             |      | 5.0 V IO                             |      | 3.3 V IO                             |      | 5.0 V IO                             |      | 3.3 V IO                             |      |      |
|     |                               |                                     |                                    | Min.                                 | Max. | Min.                                 | Max. | Min.                                 | Max. | Min.                                 | Max. | Min.                                 | Max. | Min.                                 | Max. |      |
|     |                               |                                     | Master                             | (PCSSCK + 1)*t <sub>SPSCK</sub> - 25 | -    | (PCSSCK + 1)*t <sub>SPSCK</sub> - 25 | -    | (PCSSCK + 1)*t <sub>SPSCK</sub> - 25 | -    | (PCSSCK + 1)*t <sub>SPSCK</sub> - 25 | -    | (PCSSCK + 1)*t <sub>SPSCK</sub> - 50 | -    | (PCSSCK + 1)*t <sub>SPSCK</sub> - 50 | -    |      |
|     |                               | Master Loopback <sup>5</sup>        |                                    |                                      |      |                                      |      |                                      |      |                                      |      |                                      |      |                                      |      |      |
|     |                               | Master Loopback(slow) <sup>6</sup>  |                                    |                                      |      |                                      |      |                                      |      |                                      |      |                                      |      |                                      |      |      |
| 4   | t <sub>Lag</sub> <sup>8</sup> | Enable lag time (After SPSCK delay) | Slave                              | -                                    | -    | -                                    | -    | -                                    | -    | -                                    | -    | -                                    | -    | -                                    | -    | ns   |
|     |                               |                                     | Master                             | (SCKPCS + 1)*t <sub>SPSCK</sub> - 25 | -    | (SCKPCS + 1)*t <sub>SPSCK</sub> - 25 | -    | (SCKPCS + 1)*t <sub>SPSCK</sub> - 25 | -    | (SCKPCS + 1)*t <sub>SPSCK</sub> - 25 | -    | (SCKPCS + 1)*t <sub>SPSCK</sub> - 50 | -    | (SCKPCS + 1)*t <sub>SPSCK</sub> - 50 | -    |      |
|     |                               |                                     | Master Loopback <sup>5</sup>       |                                      |      |                                      |      |                                      |      |                                      |      |                                      |      |                                      |      |      |
|     |                               |                                     | Master Loopback(slow) <sup>6</sup> |                                      |      |                                      |      |                                      |      |                                      |      |                                      |      |                                      |      |      |

Table continues on the next page...

Table 29. LPSPI electrical specifications<sup>1</sup> (continued)

| Num | Symbol             | Description                                       | Conditions                         | Run Mode <sup>2</sup>     |                           |                           |                           | HSRUN Mode <sup>2</sup>   |                           |                           |                           | VLPR Mode                 |                           |                           |                           | Unit |
|-----|--------------------|---------------------------------------------------|------------------------------------|---------------------------|---------------------------|---------------------------|---------------------------|---------------------------|---------------------------|---------------------------|---------------------------|---------------------------|---------------------------|---------------------------|---------------------------|------|
|     |                    |                                                   |                                    | 5.0 V IO                  |                           | 3.3 V IO                  |                           | 5.0 V IO                  |                           | 3.3 V IO                  |                           | 5.0 V IO                  |                           | 3.3 V IO                  |                           |      |
|     |                    |                                                   |                                    | Min.                      | Max.                      | Min.                      | Max.                      | Min.                      | Max.                      | Min.                      | Max.                      | Min.                      | Max.                      | Min.                      | Max.                      |      |
| 5   | t <sub>WSPCK</sub> | Clock(SPSC K) high or low time (SPSCK duty cycle) | Slave                              | t <sub>SPSCK</sub> /2 - 3 | t <sub>SPSCK</sub> /2 + 3 | t <sub>SPSCK</sub> /2 - 3 | t <sub>SPSCK</sub> /2 + 3 | t <sub>SPSCK</sub> /2 - 3 | t <sub>SPSCK</sub> /2 + 3 | t <sub>SPSCK</sub> /2 - 3 | t <sub>SPSCK</sub> /2 + 3 | t <sub>SPSCK</sub> /2 - 5 | t <sub>SPSCK</sub> /2 + 5 | t <sub>SPSCK</sub> /2 - 5 | t <sub>SPSCK</sub> /2 + 5 | ns   |
|     |                    |                                                   | Master                             |                           |                           |                           |                           |                           |                           |                           |                           |                           |                           |                           |                           |      |
|     |                    |                                                   | Master Loopback <sup>5</sup>       |                           |                           |                           |                           |                           |                           |                           |                           |                           |                           |                           |                           |      |
|     |                    |                                                   | Master Loopback(slow) <sup>6</sup> |                           |                           |                           |                           |                           |                           |                           |                           |                           |                           |                           |                           |      |
| 6   | t <sub>SU</sub>    | Data setup time(inputs)                           | Slave                              | 3                         | -                         | 5                         | -                         | 3                         | -                         | 5                         | -                         | 18                        | -                         | 18                        | -                         | ns   |
|     |                    |                                                   | Master                             | 29                        | -                         | 38                        | -                         | 26                        | -                         | 37                        | -                         | 72                        | -                         | 78                        | -                         |      |
|     |                    |                                                   | Master Loopback <sup>5</sup>       | 7                         | -                         | 8                         | -                         | 5                         | -                         | 7                         | -                         | 20                        | -                         | 20                        | -                         |      |
|     |                    |                                                   | Master Loopback(slow) <sup>6</sup> | 8                         | -                         | 10                        | -                         | 7                         | -                         | 9                         | -                         | 20                        | -                         | 20                        | -                         |      |
| 7   | t <sub>HI</sub>    | Data hold time(inputs)                            | Slave                              | 3                         | -                         | 3                         | -                         | 3                         | -                         | 3                         | -                         | 14                        | -                         | 14                        | -                         | ns   |
|     |                    |                                                   | Master                             | 0                         | -                         | 0                         | -                         | 0                         | -                         | 0                         | -                         | 0                         | -                         | 0                         | -                         |      |
|     |                    |                                                   | Master Loopback <sup>5</sup>       | 3                         | -                         | 3                         | -                         | 2                         | -                         | 3                         | -                         | 11                        | -                         | 11                        | -                         |      |
|     |                    |                                                   | Master Loopback(slow) <sup>6</sup> | 3                         | -                         | 3                         | -                         | 3                         | -                         | 3                         | -                         | 12                        | -                         | 12                        | -                         |      |
| 8   | t <sub>a</sub>     | Slave access time                                 | Slave                              | -                         | 50                        | -                         | 50                        | -                         | 50                        | -                         | 50                        | -                         | 100                       | -                         | 100                       | ns   |
| 9   | t <sub>dis</sub>   | Slave MISO (SOUT) disable time                    | Slave                              | -                         | 50                        | -                         | 50                        | -                         | 50                        | -                         | 50                        | -                         | 100                       | -                         | 100                       | ns   |

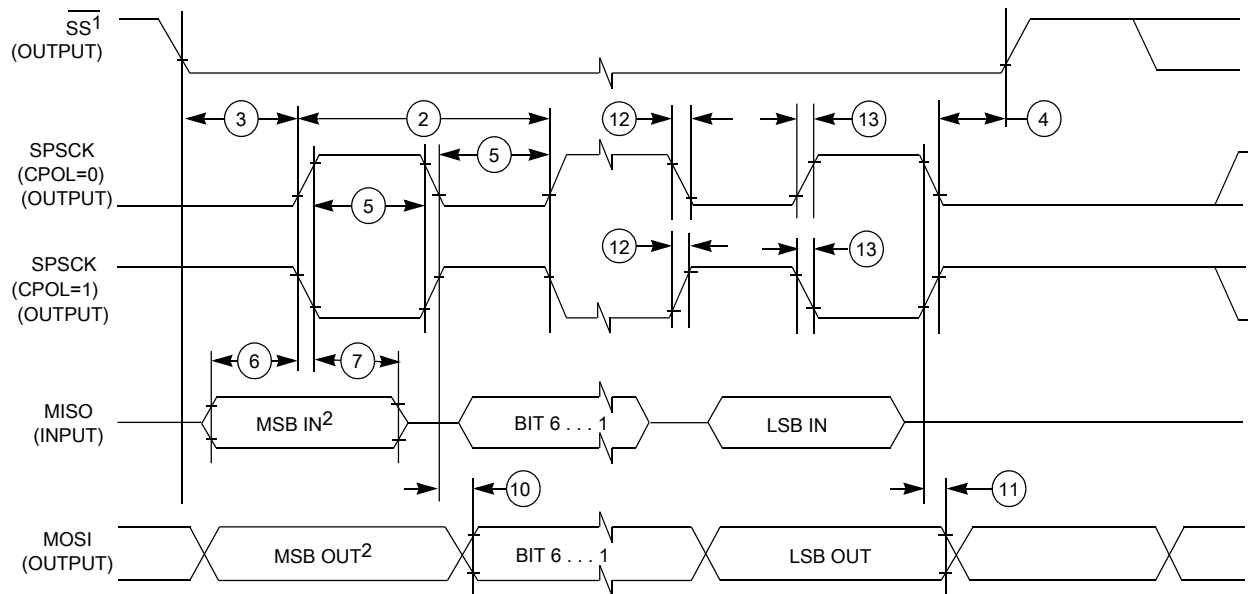
Table continues on the next page...

**Table 29. LPSPI electrical specifications<sup>1</sup> (continued)**

| Num | Symbol             | Description                    | Conditions                         | Run Mode <sup>2</sup> |      |          |      | HSRUN Mode <sup>2</sup> |      |          |      | VLPR Mode |      |          |      | Unit |
|-----|--------------------|--------------------------------|------------------------------------|-----------------------|------|----------|------|-------------------------|------|----------|------|-----------|------|----------|------|------|
|     |                    |                                |                                    | 5.0 V IO              |      | 3.3 V IO |      | 5.0 V IO                |      | 3.3 V IO |      | 5.0 V IO  |      | 3.3 V IO |      |      |
|     |                    |                                |                                    | Min.                  | Max. | Min.     | Max. | Min.                    | Max. | Min.     | Max. | Min.      | Max. | Min.     | Max. |      |
| 10  | t <sub>v</sub>     | Data valid (after SPSCCK edge) | Slave                              | -                     | 30   | -        | 39   | -                       | 26   | -        | 36   | -         | 92   | -        | 96   | ns   |
|     |                    |                                | Master                             | -                     | 12   | -        | 16   | -                       | 11   | -        | 15   | -         | 47   | -        | 48   |      |
|     |                    |                                | Master Loopback <sup>5</sup>       | -                     | 12   | -        | 16   | -                       | 11   | -        | 15   | -         | 47   | -        | 48   |      |
|     |                    |                                | Master Loopback(slow) <sup>6</sup> | -                     | 8    | -        | 10   | -                       | 7    | -        | 9    | -         | 44   | -        | 44   |      |
| 11  | t <sub>HO</sub>    | Data hold time(outputs)        | Slave                              | 4                     | -    | 4        | -    | 4                       | -    | 4        | -    | 4         | -    | 4        | -    | ns   |
|     |                    |                                | Master                             | -15                   | -    | -22      | -    | -15                     | -    | -23      | -    | -22       | -    | -29      | -    |      |
|     |                    |                                | Master Loopback <sup>5</sup>       | -10                   | -    | -14      | -    | -10                     | -    | -14      | -    | -14       | -    | -19      | -    |      |
|     |                    |                                | Master Loopback(slow) <sup>6</sup> | -15                   | -    | -22      | -    | -15                     | -    | -22      | -    | -21       | -    | -27      | -    |      |
| 12  | t <sub>RI/FI</sub> | Rise/Fall time input           | Slave                              | -                     | 1    | -        | 1    | -                       | 1    | -        | 1    | -         | 1    | -        | 1    | ns   |
|     |                    |                                | Master                             | -                     |      | -        |      | -                       |      | -        |      | -         |      | -        |      |      |
|     |                    |                                | Master Loopback <sup>5</sup>       | -                     |      | -        |      | -                       |      | -        |      | -         |      | -        |      |      |
|     |                    |                                | Master Loopback(slow) <sup>6</sup> | -                     |      | -        |      | -                       |      | -        |      | -         |      | -        |      |      |
| 13  | t <sub>RO/FO</sub> | Rise/Fall time output          | Slave                              | -                     | 25   | -        | 25   | -                       | 25   | -        | 25   | -         | 25   | -        | 25   | ns   |
|     |                    |                                | Master                             | -                     |      | -        |      | -                       |      | -        |      | -         |      | -        |      |      |
|     |                    |                                | Master Loopback <sup>5</sup>       | -                     |      | -        |      | -                       |      | -        |      | -         |      | -        |      |      |
|     |                    |                                | Master Loopback(slow) <sup>6</sup> | -                     |      | -        |      | -                       |      | -        |      | -         |      | -        |      |      |

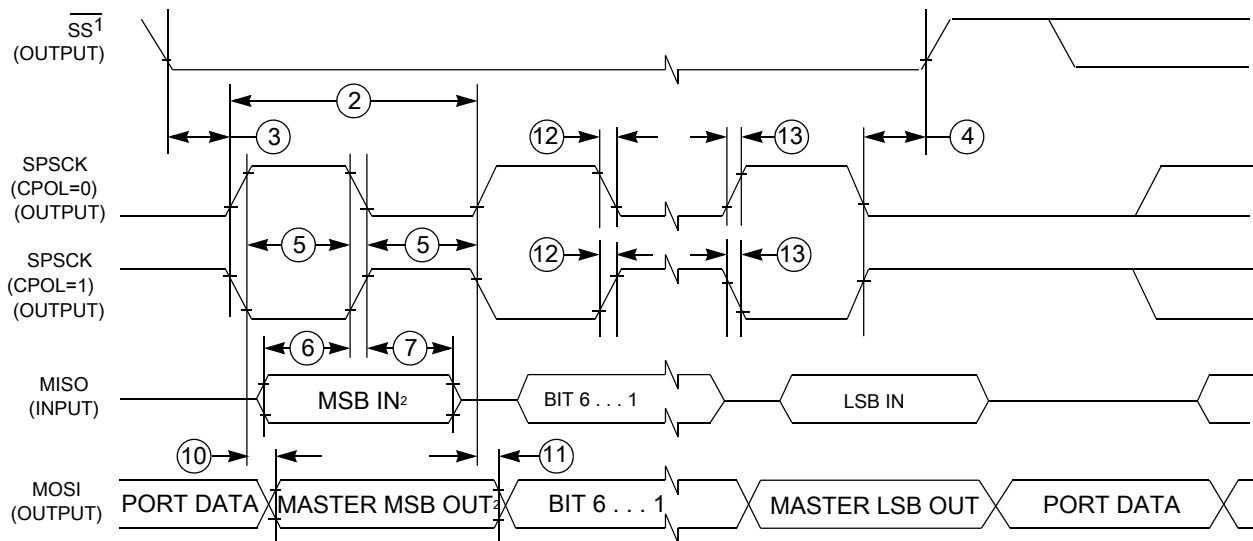
- Trace length should not exceed 11 inches for SCK pad when used in Master loopback mode.
- While transitioning from HSRUN mode to RUN mode, LPSPI output clock should not be more than 14 MHz.
- $f_{periph}$  = LPSPI peripheral clock

4.  $t_{\text{periph}} = 1/f_{\text{periph}}$
5. Master Loopback mode - In this mode LPSPI\_SCK clock is delayed for sampling the input data which is enabled by setting LPSPI\_CFGR1[SAMPLE] bit as 1. Clock pads used are PTD15 and PTE0. Applicable only for LPSPi0.
6. Master Loopback (slow) - In this mode LPSPI\_SCK clock is delayed for sampling the input data which is enabled by setting LPSPI\_CFGR1[SAMPLE] bit as 1. Clock pad used is PTB12. Applicable only for LPSPi0.
7. Set the PCSSCK configuration bit as 0, for a minimum of 1 delay cycle of LPSPI baud rate clock, where PCSSCK ranges from 0 to 255.
8. Set the SCKPCS configuration bit as 0, for a minimum of 1 delay cycle of LPSPI baud rate clock, where SCKPCS ranges from 0 to 255.



1. If configured as an output.
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

**Figure 17. LPSPI master mode timing (CPHA = 0)**



1. If configured as output
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

**Figure 18. LPSPI master mode timing (CPHA = 1)**

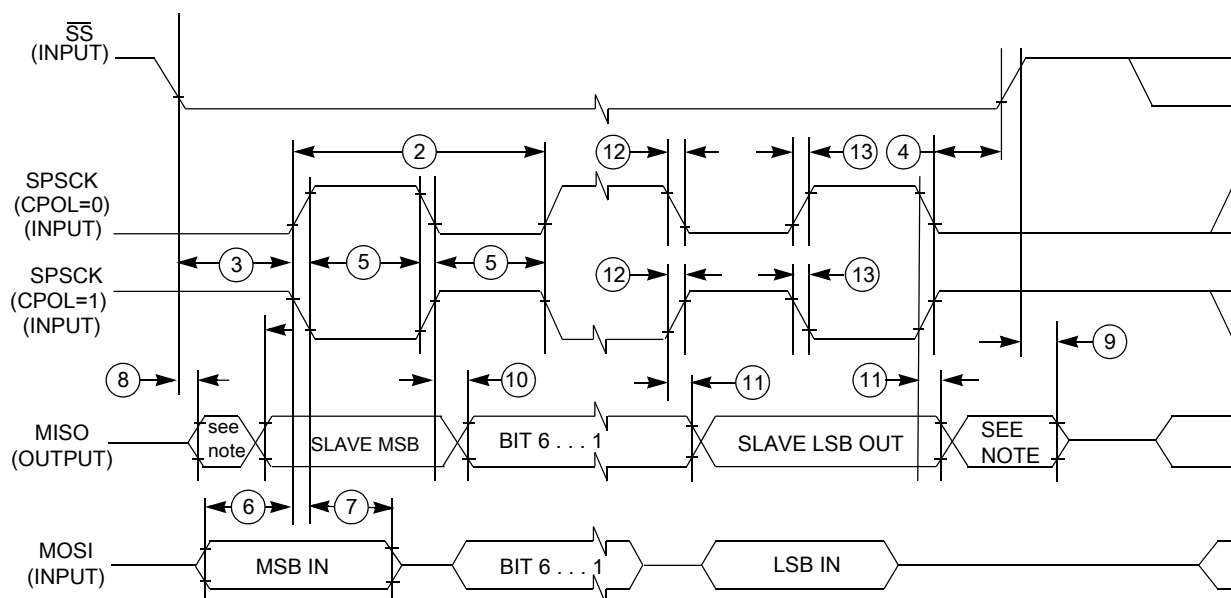


Figure 19. LPSPI slave mode timing (CPHA = 0)

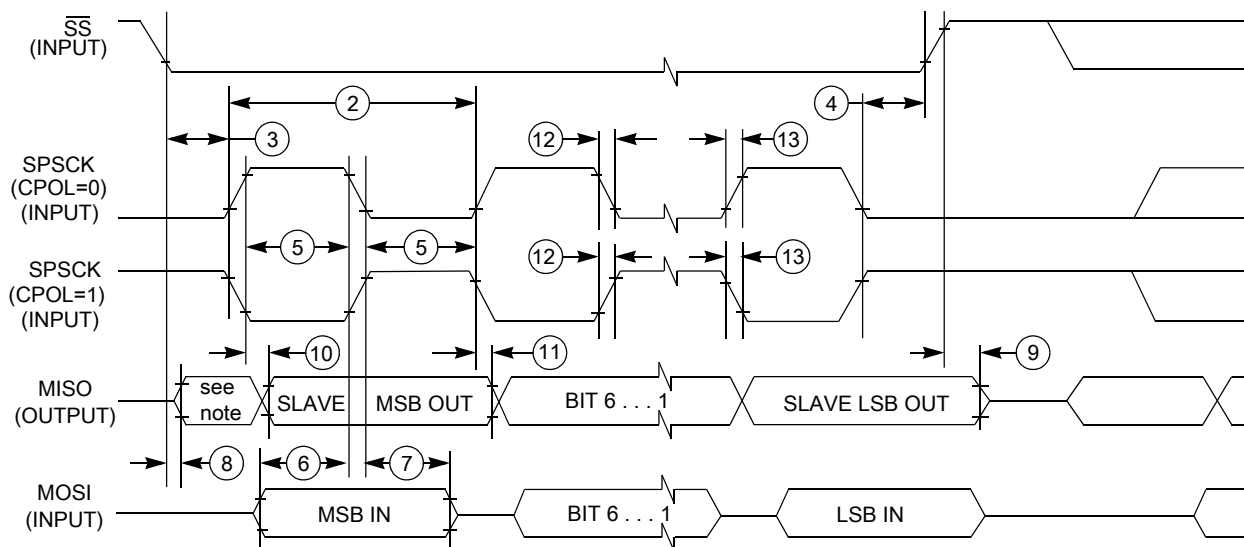


Figure 20. LPSPI slave mode timing (CPHA = 1)

### 6.5.3 LPI2C electrical specifications

See [General AC specifications](#) for LPI2C specifications.

For supported baud rate see section 'Chip-specific LPI2C information' of the *Reference Manual*.

### 6.5.4 FlexCAN electrical specifications

For supported baud rate, see section 'Protocol timing' of the *Reference Manual*.

### 6.5.5 SAI electrical specifications

The following table describes the SAI electrical characteristics.

- Measurements are with maximum output load of 50 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN ), the interface should be OFF.

**Table 30. Master mode timing specifications**

| Symbol | Description                         | Min. | Max. | Unit        |
|--------|-------------------------------------|------|------|-------------|
| —      | Operating voltage                   | 2.97 | 3.6  | V           |
| S1     | SAI_MCLK cycle time                 | 40   | —    | ns          |
| S2     | SAI_MCLK pulse width high/low       | 45%  | 55%  | MCLK period |
| S3     | SAI_BCLK cycle time                 | 80   | —    | ns          |
| S4     | SAI_BCLK pulse width high/low       | 45%  | 55%  | BCLK period |
| S5     | SAI_RXD input setup before SAI_BCLK | 28   | —    | ns          |
| S6     | SAI_RXD input hold after SAI_BCLK   | 0    | —    | ns          |
| S7     | SAI_BCLK to SAI_TXD output valid    | —    | 8    | ns          |
| S8     | SAI_BCLK to SAI_TXD output invalid  | -2   | —    | ns          |
| S9     | SAI_FS input setup before SAI_BCLK  | 28   | —    | ns          |
| S10    | SAI_FS input hold after SAI_BCLK    | 0    | —    | ns          |
| S11    | SAI_BCLK to SAI_FS output valid     | —    | 8    | ns          |
| S12    | SAI_BCLK to SAI_FS output invalid   | -2   | —    | ns          |

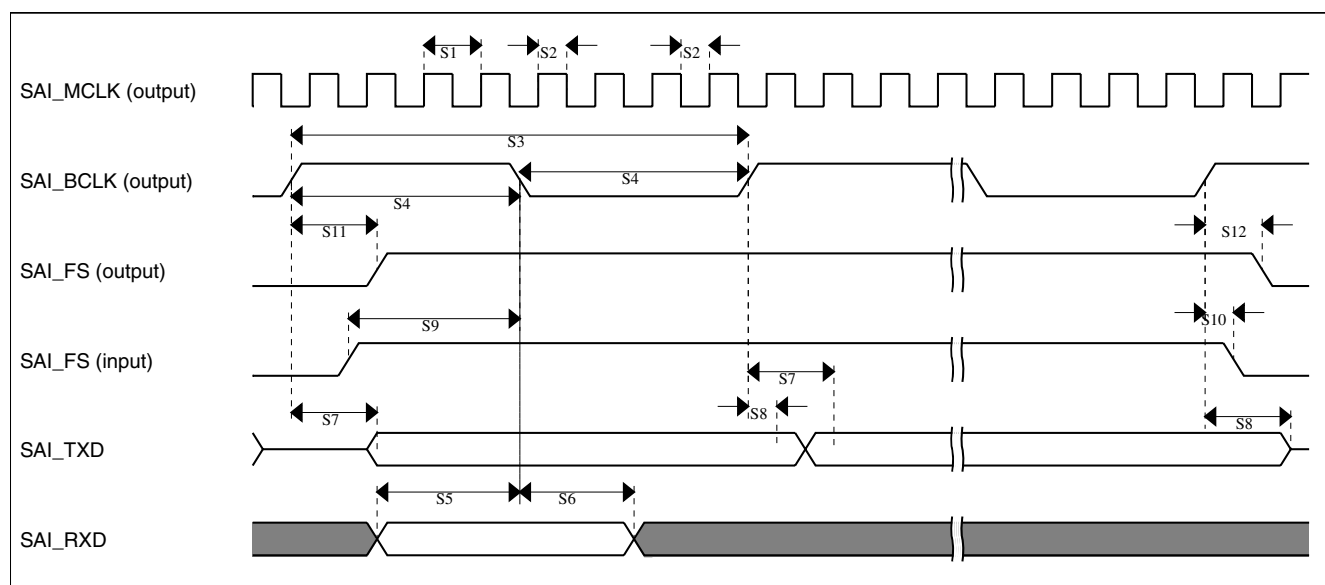


Figure 21. SAI Timing — Master modes

Table 31. Slave mode timing specifications

| Symbol           | Description                           | Min. | Max. | Unit        |
|------------------|---------------------------------------|------|------|-------------|
| —                | Operating voltage                     | 2.97 | 3.6  | V           |
| S13              | SAI_BCLK cycle time (input)           | 80   | —    | ns          |
| S14 <sup>1</sup> | SAI_BCLK pulse width high/low (input) | 45%  | 55%  | BCLK period |
| S15              | SAI_RXD input setup before SAI_BCLK   | 8    | —    | ns          |
| S16              | SAI_RXD input hold after SAI_BCLK     | 2    | —    | ns          |
| S17              | SAI_BCLK to SAI_TXD output valid      | —    | 28   | ns          |
| S18              | SAI_BCLK to SAI_TXD output invalid    | 0    | —    | ns          |
| S19              | SAI_FS input setup before SAI_BCLK    | 8    | —    | ns          |
| S20              | SAI_FS input hold after SAI_BCLK      | 2    | —    | ns          |
| S21              | SAI_BCLK to SAI_FS output valid       | —    | 28   | ns          |
| S22              | SAI_BCLK to SAI_FS output invalid     | 0    | —    | ns          |

1. The slave mode parameters (S15 - S22) assume 50% duty cycle on SAI\_BCLK input. Any change in SAI\_BCLK duty cycle input must be taken care during the board design or by the master timing.

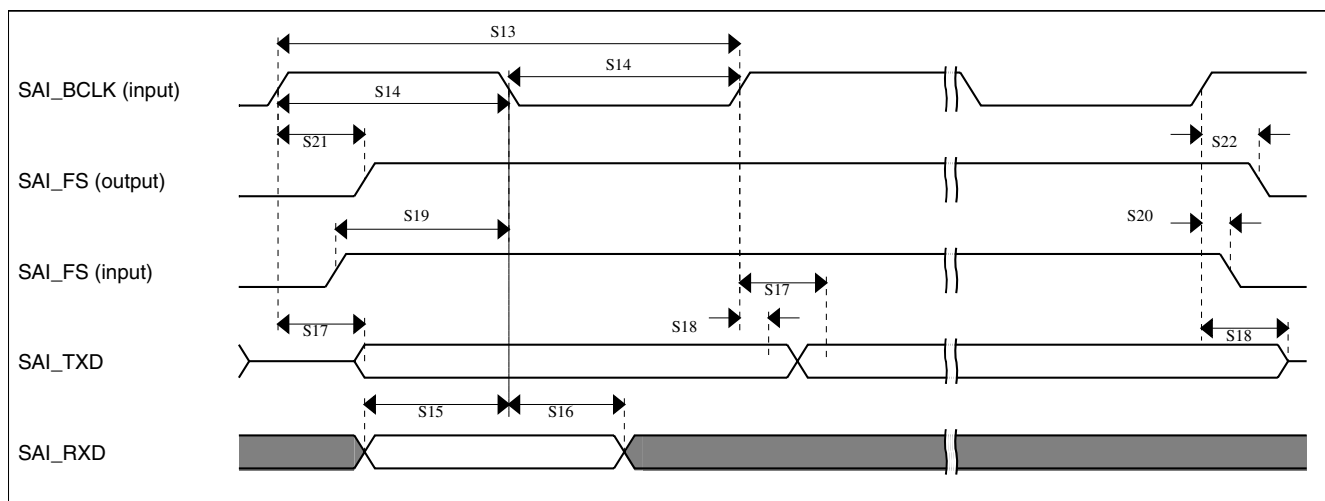


Figure 22. SAI Timing — Slave modes

### 6.5.6 Ethernet AC specifications

The following timing specs are defined at the chip I/O pin and must be translated appropriately to arrive at timing specs/constraints for the physical interface.

The following table describes the MII electrical characteristics.

- Measurements are with maximum output load of 25 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN ), the interface should be OFF.

Table 32. MII signal switching specifications

| Symbol | Description                           | Min. | Max. | Unit         |
|--------|---------------------------------------|------|------|--------------|
| —      | RXCLK frequency                       | —    | 25   | MHz          |
| MII1   | RXCLK pulse width high                | 35%  | 65%  | RXCLK period |
| MII2   | RXCLK pulse width low                 | 35%  | 65%  | RXCLK period |
| MII3   | RXD[3:0], RXDV, RXER to RXCLK setup   | 5    | —    | ns           |
| MII4   | RXCLK to RXD[3:0], RXDV, RXER hold    | 5    | —    | ns           |
| —      | TXCLK frequency                       | —    | 25   | MHz          |
| MII5   | TXCLK pulse width high                | 35%  | 65%  | TXCLK period |
| MII6   | TXCLK pulse width low                 | 35%  | 65%  | TXCLK period |
| MII7   | TXCLK to TXD[3:0], TXEN, TXER invalid | 2    | —    | ns           |
| MII8   | TXCLK to TXD[3:0], TXEN, TXER valid   | —    | 25   | ns           |

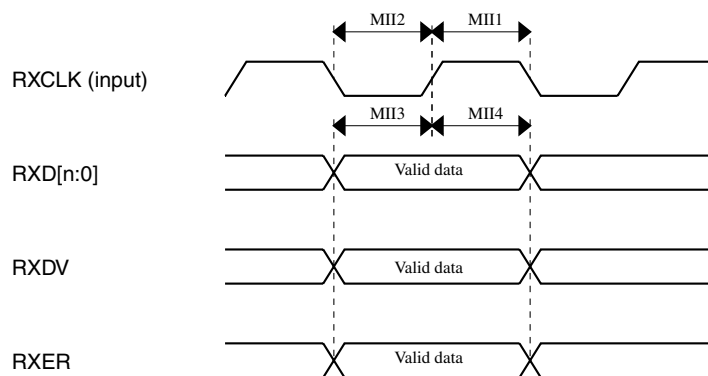


Figure 23. MII receive diagram

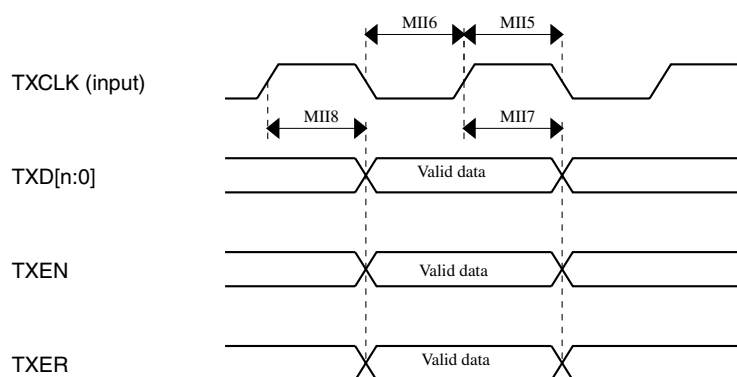


Figure 24. MII transmit signal diagram

The following table describes the RMII electrical characteristics.

- Measurements are with maximum output load of 25 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN ), the interface should be OFF.

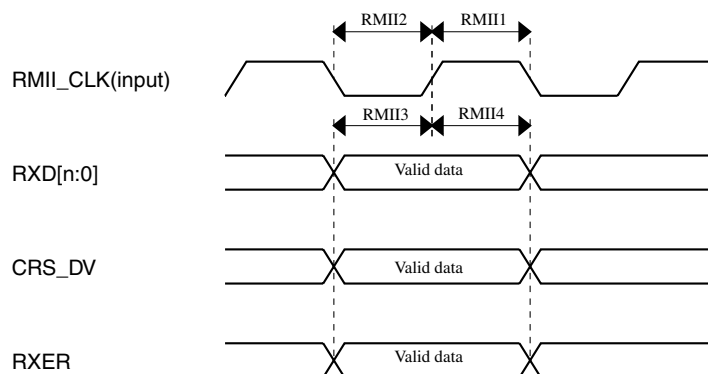
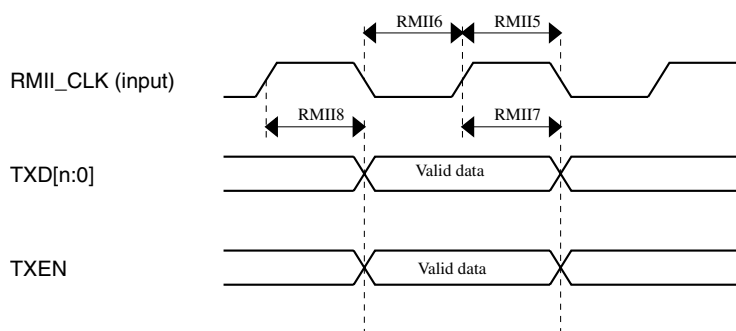
Table 33. RMII signal switching specifications

| Symbol       | Description                              | Min. | Max. | Unit            |
|--------------|------------------------------------------|------|------|-----------------|
| —            | RMII input clock RMII_CLK Frequency      | —    | 50   | MHz             |
| RMII1, RMII5 | RMII_CLK pulse width high                | 35%  | 65%  | RMII_CLK period |
| RMII2, RMII6 | RMII_CLK pulse width low                 | 35%  | 65%  | RMII_CLK period |
| RMII3        | RXD[1:0], CRS_DV, RXER to RMII_CLK setup | 4    | —    | ns              |
| RMII4        | RMII_CLK to RXD[1:0], CRS_DV, RXER hold  | 2    | —    | ns              |

Table continues on the next page...

**Table 33. RMI signal switching specifications  
(continued)**

| Symbol | Description                        | Min. | Max. | Unit |
|--------|------------------------------------|------|------|------|
| RMII7  | RMII_CLK to TXD[1:0], TXEN invalid | 2    | —    | ns   |
| RMII8  | RMII_CLK to TXD[1:0], TXEN valid   | —    | 15   | ns   |

**Figure 25. RMI receive diagram****Figure 26. RMI transmit diagram**

The following table describes the MDIO electrical characteristics.

- Measurements are with maximum output load of 25 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN ), the interface should be OFF.
- MDIO pin must have external Pull-up.

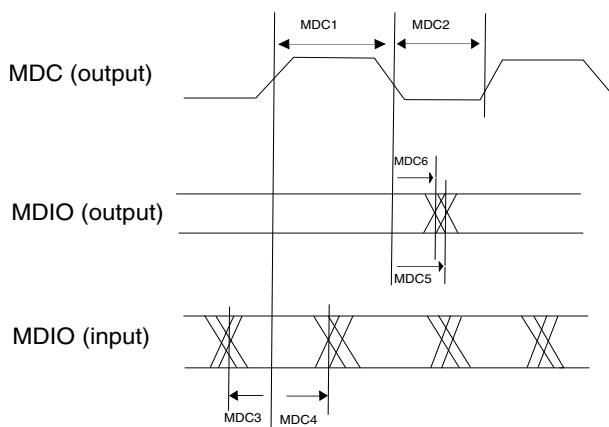
**Table 34. MDIO timing specifications**

| Symbol | Description         | Min. | Max. | Unit |
|--------|---------------------|------|------|------|
| —      | MDC Clock Frequency | —    | 2.5  | MHz  |

Table continues on the next page...

**Table 34. MDIO timing specifications (continued)**

| Symbol | Description                                                         | Min. | Max. | Unit       |
|--------|---------------------------------------------------------------------|------|------|------------|
| MDC1   | MDC pulse width high                                                | 40%  | 60%  | MDC period |
| MDC2   | MDC pulse width low                                                 | 40%  | 60%  | MDC period |
| MDC3   | MDIO (input) to MDC rising edge setup                               | 25   | —    | ns         |
| MDC4   | MDIO (input) to MDC rising edge hold                                | 0    | —    | ns         |
| MDC5   | MDC falling edge to MDIO output valid (maximum propagation delay)   | —    | 25   | ns         |
| MDC6   | MDC falling edge to MDIO output invalid (minimum propagation delay) | -10  | —    | ns         |

**Figure 27. MII/RMII serial management channel timing diagram**

### 6.5.7 Clockout frequency

Maximum supported clock out frequency for this device is 20 MHz

## 6.6 Debug modules

### 6.6.1 SWD electrical specifications

Table 35. SWD electrical specifications

| Symbol | Description                                     | Run Mode |          |          |          | HSRUN Mode |          |          |          | VLPR Mode |          |          |          | Unit |
|--------|-------------------------------------------------|----------|----------|----------|----------|------------|----------|----------|----------|-----------|----------|----------|----------|------|
|        |                                                 | 5.0 V IO |          | 3.3 V IO |          | 5.0 V IO   |          | 3.3 V IO |          | 5.0 V IO  |          | 3.3 V IO |          |      |
|        |                                                 | Min.     | Max.     | Min.     | Max.     | Min.       | Max.     | Min.     | Max.     | Min.      | Max.     | Min.     | Max.     |      |
| S1     | SWD_CLK frequency of operation                  | -        | 25       | -        | 25       | -          | 25       | -        | 25       | -         | 10       | -        | 10       | MHz  |
| S2     | SWD_CLK cycle period                            | 1/S1     | -        | 1/S1     | -        | 1/S1       | -        | 1/S1     | -        | 1/S1      | -        | 1/S1     | -        | ns   |
| S3     | SWD_CLK clock pulse width                       | S2/2 - 5 | S2/2 + 5 | S2/2 - 5 | S2/2 + 5 | S2/2 - 5   | S2/2 + 5 | S2/2 - 5 | S2/2 + 5 | S2/2 - 5  | S2/2 + 5 | S2/2 - 5 | S2/2 + 5 | ns   |
| S4     | SWD_CLK rise and fall times                     | -        | 1        | -        | 1        | -          | 1        | -        | 1        | -         | 1        | -        | 1        | ns   |
| S9     | SWD_DIO input data setup time to SWD_CLK rise   | 4        | -        | 4        | -        | 4          | -        | 4        | -        | 16        | -        | 16       | -        | ns   |
| S10    | SWD_DIO input data hold time after SWD_CLK rise | 3        | -        | 3        | -        | 3          | -        | 3        | -        | 10        | -        | 10       | -        | ns   |
| S11    | SWD_CLK high to SWD_DIO data valid              | -        | 28       | -        | 38       | -          | 28       | -        | 38       | -         | 70       | -        | 77       | ns   |
| S12    | SWD_CLK high to SWD_DIO high-Z                  | -        | 28       | -        | 38       | -          | 28       | -        | 38       | -         | 70       | -        | 77       | ns   |
| S13    | SWD_CLK high to SWD_DIO data invalid            | 0        | -        | 0        | -        | 0          | -        | 0        | -        | 0         | -        | 0        | -        | ns   |

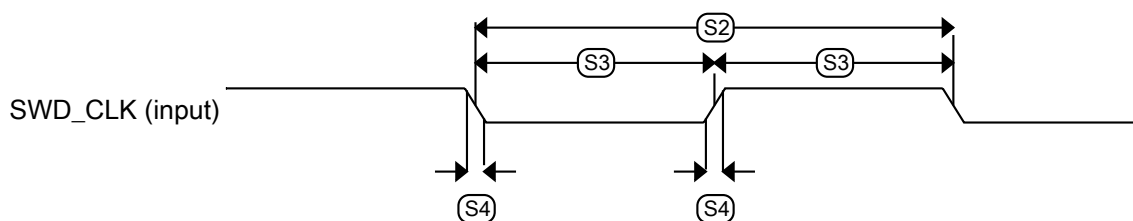


Figure 28. Serial wire clock input timing

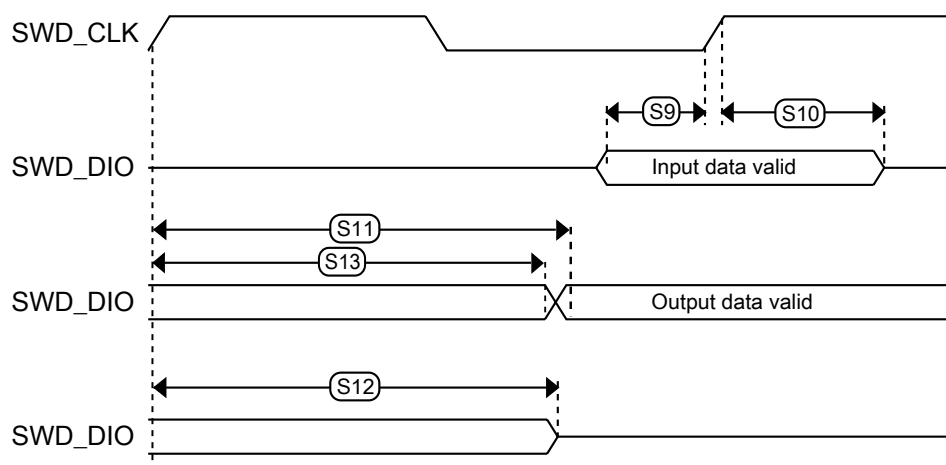


Figure 29. Serial wire data timing

## 6.6.2 Trace electrical specifications

The following table describes the Trace electrical characteristics.

- Measurements are with maximum output load of 50 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN ), the interface should be OFF.

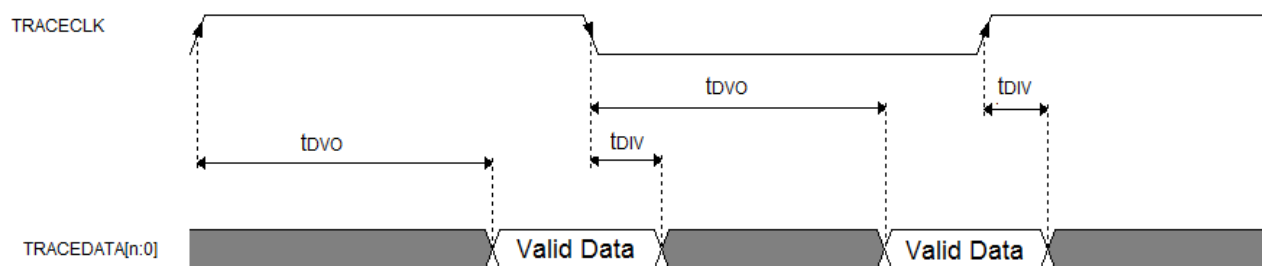
Table 36. Trace specifications

|   | Symbol | Description      | RUN Mode |    |    | HSRUN Mode |    | VLPR Mode | Unit |
|---|--------|------------------|----------|----|----|------------|----|-----------|------|
| — | Fsys   | System frequency | 80       | 48 | 40 | 112        | 80 | 4         | MHz  |

Table continues on the next page...

**Table 36. Trace specifications (continued)**

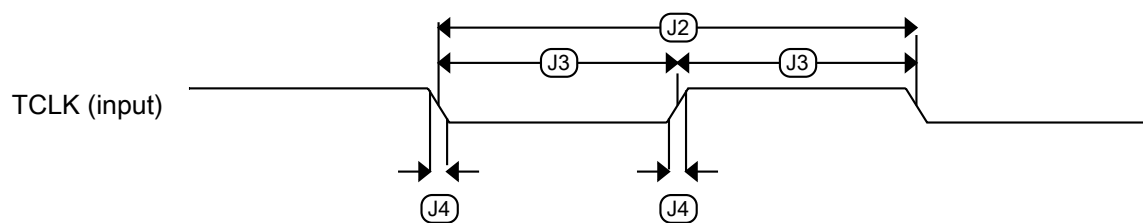
|                    | Symbol             | Description         | RUN Mode |    |    | HSRUN Mode |       | VLPR Mode | Unit |
|--------------------|--------------------|---------------------|----------|----|----|------------|-------|-----------|------|
| Trace on fast pads | $f_{\text{TRACE}}$ | Max Trace frequency | 80       | 48 | 40 | 74.667     | 80    | 4         | MHz  |
|                    | $t_{\text{DVO}}$   | Data Output Valid   | 4        | 4  | 4  | 4          | 4     | 20        | ns   |
|                    | $t_{\text{DIV}}$   | Data Output Invalid | -2       | -2 | -2 | -2         | -2    | -10       | ns   |
| Trace on slow pads | $f_{\text{TRACE}}$ | Max Trace frequency | 22.86    | 24 | 20 | 22.4       | 22.86 | 4         | MHz  |
|                    | $t_{\text{DVO}}$   | Data Output Valid   | 8        | 8  | 8  | 8          | 8     | 20        | ns   |
|                    | $t_{\text{DIV}}$   | Data Output Invalid | -4       | -4 | -4 | -4         | -4    | -10       | ns   |

**Figure 30. TRACE CLKOUT specifications**

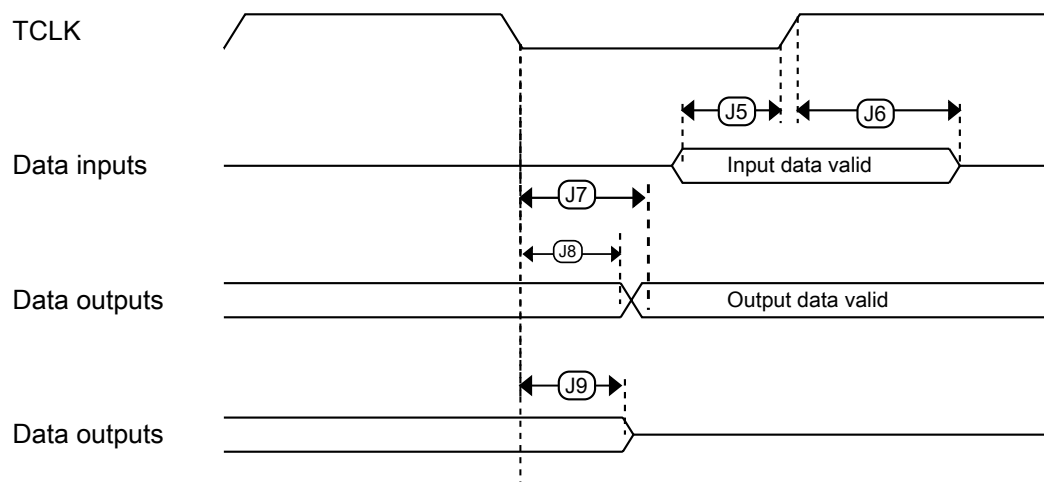
### 6.6.3 JTAG electrical specifications

Table 37. JTAG electrical specifications

| Symbol | Description                                        | Run Mode |          |          |          | HSRUN Mode |          |          |          | VLPR Mode |          |          |          | Unit |
|--------|----------------------------------------------------|----------|----------|----------|----------|------------|----------|----------|----------|-----------|----------|----------|----------|------|
|        |                                                    | 5.0 V IO |          | 3.3 V IO |          | 5.0 V IO   |          | 3.3 V IO |          | 5.0 V IO  |          | 3.3 V IO |          |      |
|        |                                                    | Min.     | Max.     | Min.     | Max.     | Min.       | Max.     | Min.     | Max.     | Min.      | Max.     | Min.     | Max.     |      |
| J1     | TCLK frequency of operation                        |          |          |          |          |            |          |          |          |           |          |          |          | MHz  |
|        | Boundary Scan                                      | -        | 20       | -        | 20       | -          | 20       | -        | 20       | -         | 10       | -        | 10       |      |
|        | JTAG                                               | -        | 20       | -        | 20       | -          | 20       | -        | 20       | -         | 10       | -        | 10       |      |
| J2     | TCLK cycle period                                  | 1/J1     | -        | 1/J1     | -        | 1/J1       | -        | 1/J1     | -        | 1/J1      | -        | 1/J1     | -        | ns   |
| J3     | TCLK clock pulse width                             |          |          |          |          |            |          |          |          |           |          |          |          | ns   |
|        | Boundary Scan                                      | J2/2 - 5 | J2/2 + 5 | J2/2 - 5 | J2/2 + 5 | J2/2 - 5   | J2/2 + 5 | J2/2 - 5 | J2/2 + 5 | J2/2 - 5  | J2/2 + 5 | J2/2 - 5 | J2/2 + 5 |      |
|        | JTAG                                               |          |          |          |          |            |          |          |          |           |          |          |          |      |
| J4     | TCLK rise and fall times                           | -        | 1        | -        | 1        | -          | 1        | -        | 1        | -         | 1        | -        | 1        | ns   |
| J5     | Boundary scan input data setup time to TCLK rise   | 5        | -        | 5        | -        | 5          | -        | 5        | -        | 15        | -        | 15       | -        | ns   |
| J6     | Boundary scan input data hold time after TCLK rise | 5        | -        | 5        | -        | 5          | -        | 5        | -        | 8         | -        | 8        | -        | ns   |
| J7     | TCLK low to boundary scan output data valid        | -        | 28       | -        | 32       | -          | 28       | -        | 32       | -         | 80       | -        | 80       | ns   |
| J8     | TCLK low to boundary scan output data invalid      | 0        | -        | 0        | -        | 0          | -        | 0        | -        | 0         | -        | 0        | -        |      |
| J9     | TCLK low to boundary scan output high-Z            | -        | 28       | -        | 32       | -          | 28       | -        | 32       | -         | 80       | -        | 80       | ns   |
| J10    | TMS, TDI input data setup time to TCLK rise        | 3        | -        | 3        | -        | 3          | -        | 3        | -        | 15        | -        | 15       | -        | ns   |
| J11    | TMS, TDI input data hold time after TCLK rise      | 2        | -        | 2        | -        | 2          | -        | 2        | -        | 8         | -        | 8        | -        | ns   |
| J12    | TCLK low to TDO data valid                         | -        | 28       | -        | 32       | -          | 28       | -        | 32       | -         | 80       | -        | 80       | ns   |
| J13    | TCLK low to TDO data invalid                       | 0        | -        | 0        | -        | 0          | -        | 0        | -        | 0         | -        | 0        | -        | ns   |
| J14    | TCLK low to TDO high-Z                             | -        | 28       | -        | 32       | -          | 28       | -        | 32       | -         | 80       | -        | 80       | ns   |



**Figure 31. Test clock input timing**



**Figure 32. Boundary scan (JTAG) timing**

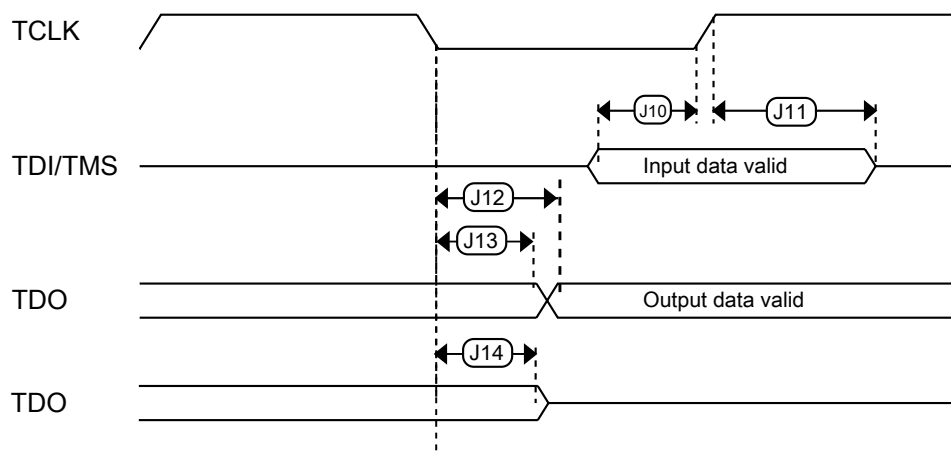


Figure 33. Test Access Port timing

## 7 Thermal attributes

### 7.1 Description

The tables in the following sections describe the thermal characteristics of the device.

#### NOTE

Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting side (board) temperature, ambient temperature, air flow, power dissipation or other components on the board, and board thermal resistance.

### 7.2 Thermal characteristics

Table 38. Thermal characteristics for the 64/100-pin LQFP package

| Rating                                                                       | Conditions              | Symbol           | Packages | Values        |               |           | Unit |
|------------------------------------------------------------------------------|-------------------------|------------------|----------|---------------|---------------|-----------|------|
|                                                                              |                         |                  |          | MWCT101<br>4S | MWCT101<br>5S | MWCT1016S |      |
| Thermal resistance, Junction to Ambient (Natural Convection) <sup>1, 2</sup> | Single layer board (1s) | $R_{\theta JA}$  | 64       | 61            | TBD           | NA        | °C/W |
|                                                                              |                         |                  | 100      | 52            | TBD           | NA        | °C/W |
| Thermal resistance, Junction to Ambient (Natural Convection) <sup>1</sup>    | Two layer board (1s1p)  | $R_{\theta JA}$  | 64       | 45            | TBD           | NA        | °C/W |
|                                                                              |                         |                  | 100      | 42            | TBD           | NA        | °C/W |
| Thermal resistance, Junction to Ambient (Natural Convection) <sup>1, 2</sup> | Four layer board (2s2p) | $R_{\theta JA}$  | 64       | 43            | TBD           | NA        | °C/W |
|                                                                              |                         |                  | 100      | 40            | TBD           | NA        | °C/W |
| Thermal resistance, Junction to Ambient (@200 ft/min) <sup>1, 3</sup>        | Single layer board (1s) | $R_{\theta JMA}$ | 64       | 49            | TBD           | NA        | °C/W |
|                                                                              |                         |                  | 100      | 42            | TBD           | NA        | °C/W |
| Thermal resistance, Junction to Ambient (@200 ft/min) <sup>1</sup>           | Two layer board (1s1p)  | $R_{\theta JMA}$ | 64       | 38            | TBD           | NA        | °C/W |
|                                                                              |                         |                  | 100      | 35            | TBD           | NA        | °C/W |
| Thermal resistance, Junction to Ambient (@200 ft/min) <sup>1, 3</sup>        | Four layer board (2s2p) | $R_{\theta JMA}$ | 64       | 36            | TBD           | NA        | °C/W |
|                                                                              |                         |                  | 100      | 34            | TBD           | NA        | °C/W |
| Thermal resistance, Junction to Board <sup>4</sup>                           | —                       | $R_{\theta JB}$  | 64       | 25            | TBD           | NA        | °C/W |
|                                                                              |                         |                  | 100      | 25            | TBD           | NA        | °C/W |
| Thermal resistance, Junction to Case <sup>5</sup>                            | —                       | $R_{\theta JC}$  | 64       | 12            | TBD           | NA        | °C/W |
|                                                                              |                         |                  | 100      | 12            | TBD           | NA        | °C/W |
| Thermal resistance, Junction to Package Top <sup>6</sup>                     | Natural Convection      | $\Psi_{JT}$      | 64       | 2             | TBD           | NA        | °C/W |
|                                                                              |                         |                  | 100      | 2             | TBD           | NA        | °C/W |

1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
2. Per JEDEC JESD51-2 with natural convection for horizontally oriented board. Board meets JESD51-9 specification for 1s or 2s2p board, respectively.
3. Per JEDEC JESD51-6 with forced convection for horizontally oriented board. Board meets JESD51-9 specification for 1s or 2s2p board, respectively.
4. Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
5. Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).
6. Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2. When Greek letters are not available, the thermal characterization parameter is written as Psi-JT.

### 7.3 General notes for specifications at maximum junction temperature

An estimation of the chip junction temperature,  $T_J$ , can be obtained from this equation:

$$T_J = T_A + (R_{\theta JA} \times P_D)$$

where:

- $T_A$  = ambient temperature for the package (°C)
- $R_{\theta JA}$  = junction to ambient thermal resistance (°C/W)
- $P_D$  = power dissipation in the package (W)

The junction to ambient thermal resistance is an industry standard value that provides a quick and easy estimation of thermal performance. Unfortunately, there are two values in common usage: the value determined on a single layer board and the value obtained on a board with two planes. For packages such as the PBGA, these values can be different by a factor of two. Which value is closer to the application depends on the power dissipated by other components on the board. The value obtained on a single layer board is appropriate for the tightly packed printed circuit board. The value obtained on the board with the internal planes is usually appropriate if the board has low power dissipation and the components are well separated.

When a heat sink is used, the thermal resistance is expressed in the following equation as the sum of a junction-to-case thermal resistance and a case-to-ambient thermal resistance:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$$

where:

- $R_{\theta JA}$  = junction to ambient thermal resistance (°C/W)
- $R_{\theta JC}$  = junction to case thermal resistance (°C/W)
- $R_{\theta CA}$  = case to ambient thermal resistance (°C/W)

$R_{\theta JC}$  is device related and cannot be influenced by the user. The user controls the thermal environment to change the case to ambient thermal resistance,  $R_{\theta CA}$ . For instance, the user can change the size of the heat sink, the air flow around the device, the interface material, the mounting arrangement on printed circuit board, or change the thermal dissipation on the printed circuit board surrounding the device.

To determine the junction temperature of the device in the application when heat sinks are not used, the Thermal Characterization Parameter ( $\Psi_{JT}$ ) can be used to determine the junction temperature with a measurement of the temperature at the top center of the package case using this equation:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$

where:

- $T_T$  = thermocouple temperature on top of the package ( $^{\circ}\text{C}$ )
- $\Psi_{JT}$  = thermal characterization parameter ( $^{\circ}\text{C}/\text{W}$ )
- $P_D$  = power dissipation in the package (W)

The thermal characterization parameter is measured per JESD51-2 specification using a 40 gauge type T thermocouple epoxied to the top center of the package case. The thermocouple should be positioned so that the thermocouple junction rests on the package. A small amount of epoxy is placed over the thermocouple junction and over about 1 mm of wire extending from the junction. The thermocouple wire is placed flat against the package case to avoid measurement errors caused by cooling effects of the thermocouple wire.

## 8 Dimensions

### 8.1 Obtaining package dimensions

Package dimensions are provided in the package drawings.

To find a package drawing, go to <http://www.nxp.com> and perform a keyword search for the drawing's document number:

| Package option | Document Number |
|----------------|-----------------|
| 64-pin LQFP    | 98ASS23234W     |
| 100-pin LQFP   | 98ASS23308W     |

## 9 Pinouts

### 9.1 Package pinouts and signal descriptions

For package pinouts and signal descriptions, refer to the Reference Manual.

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